

Investors' Guide

November 7, 2025

Tokyo Electron Limited



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1. TEL Overview



Company Profile

Established

November 11, 1963

Major Products and Services

Semiconductor Production Equipment

Capital

54.9 Billion Yen

Sales/Profit

Net sales 2,431.5 Billion Yen / Operating income 697.3 Billion Yen / Operating margin 28.7% (Fiscal 2025)

Number of Employees

2,347 (non-consolidated) 20,273 (consolidated)

Global Network

Japan: 6 companies / 30 sites

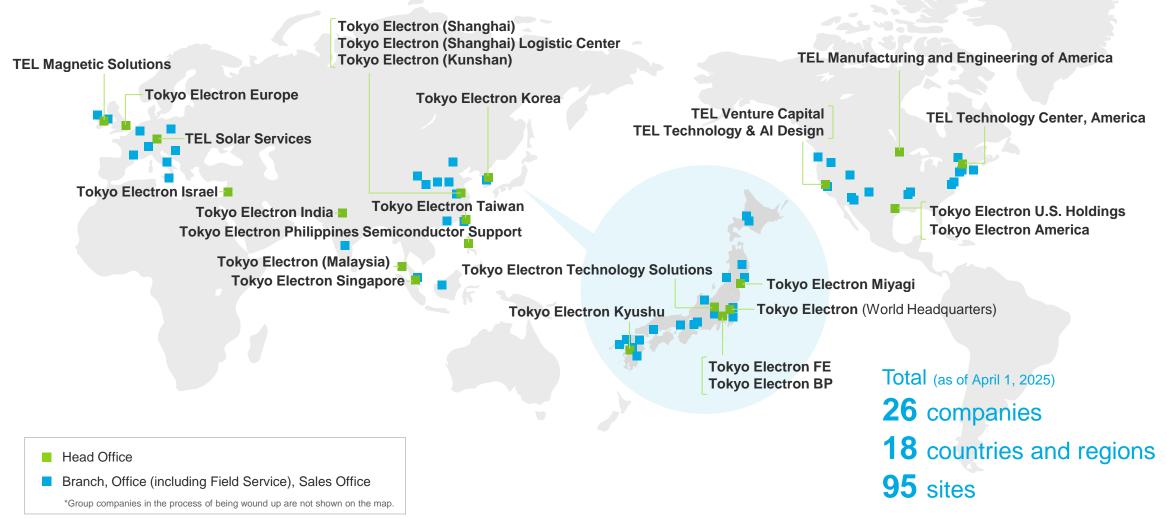
Overseas: 20 companies / 17 countries and regions / 65 sites

Total: 26 companies / 18 countries and regions / 95 sites (consolidated)

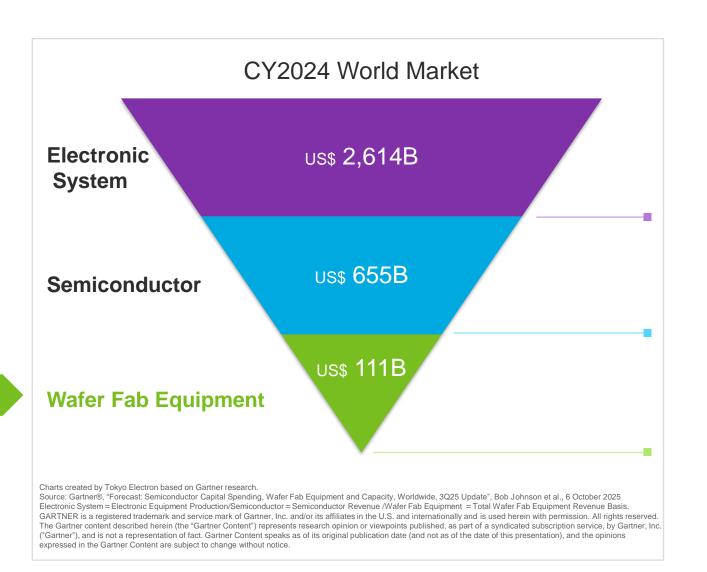
(as of April 1, 2025)

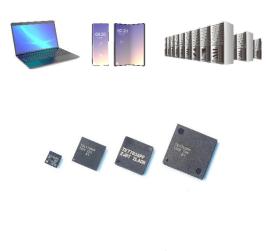


(As of Nov. 1, 2025)



The Market TEL Participates in







The market TEL

participates in

TEL's Growth

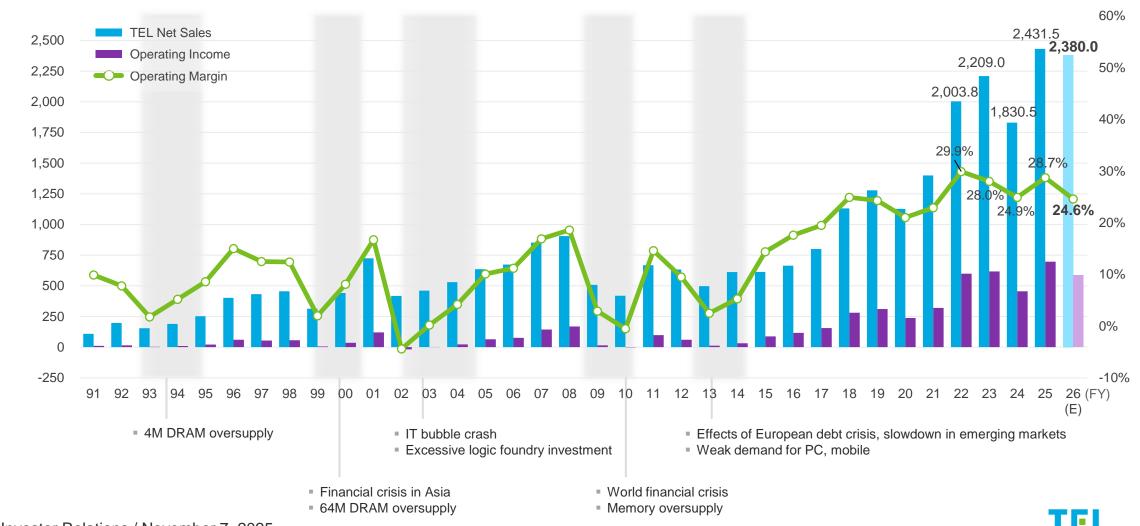




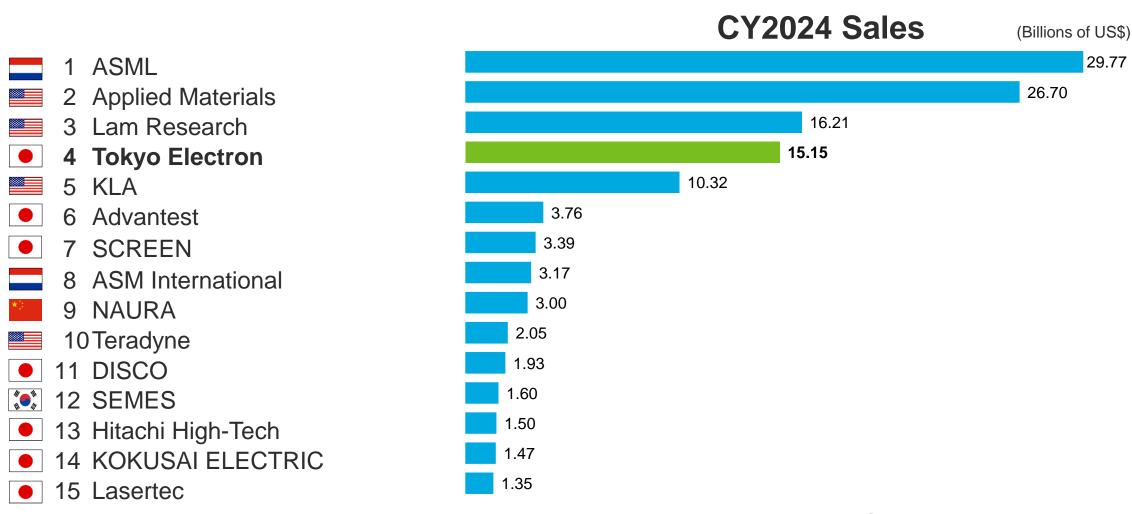


Financial Performance: Sales and Operating Margin

(Billion Yen)

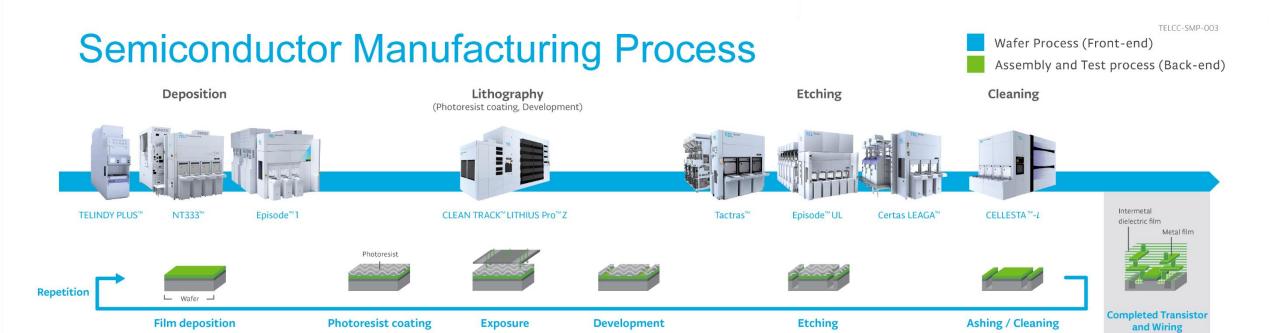


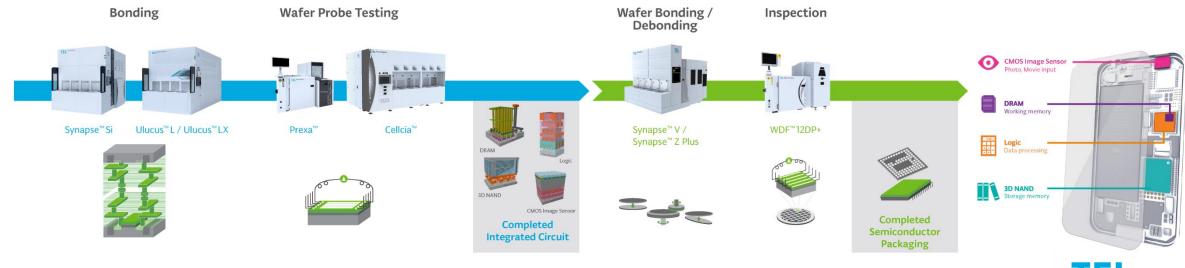
CY2024 SPE Makers Top 15



Source: TechInsights Inc., May 2025

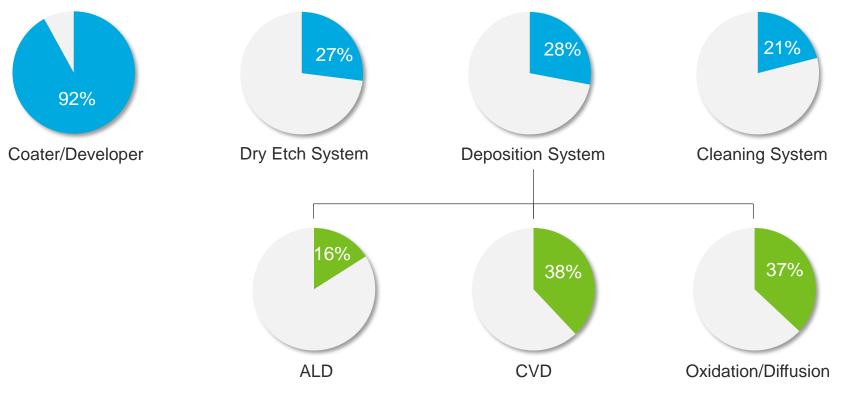






TEL

World Market Share of Major Products (CY2024)



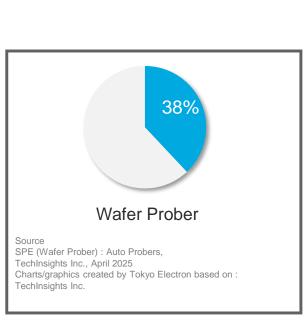
Source

SPE (excluding Wafer Prober): Gartner®, Market Share: Semiconductor Wafer Fab Equipment, Worldwide, 2024, Bob Johnson and Menglin Cao, 21 April 2025, Revenue from Shipments basis. Chart created by TEL based on Gartner research. Gartner research. Calculations performed by TEL.

Coater/Developer: Photoresist Processing (Track), Dry Etch System: Dry Etch, Deposition System: Tube CVD + Atomic Layer Deposition Tools + Oxidation/Diffusion Furnaces + Nontube LPCVD, ALD: Atomic Layer Deposition Tools, CVD: Tube CVD + Nontube LPCVD, Oxidation/Diffusion: Oxidation/diffusion Furnaces, Cleaning System: Single Wafer Processors + Wet Stations + Batch Spray Processors + Other Clean Equipment, Wafer Bonder: Wafer Bonder.

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Wafer Bonder

32%

TEL's Strengths

Have advanced products for the 4 key process







*TEL estimate

100%

Market share of coater/developer for EUVL



*TEL estimate

No.1

Worldwide installed base

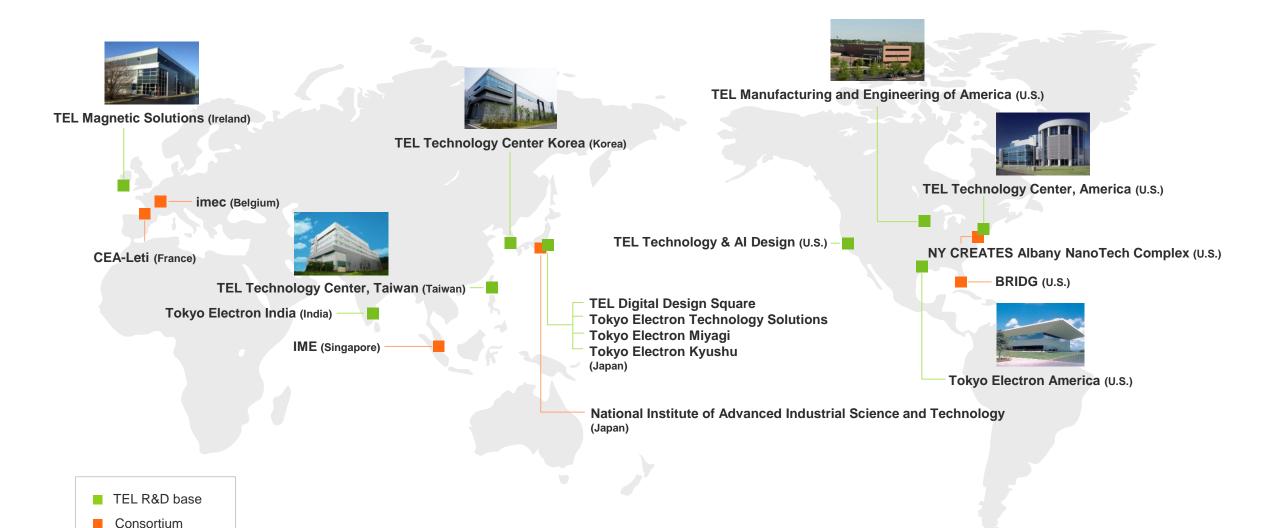
Annual increase by about 4,000~6,000 units*1
Industry's largest installed base 98,000 units*2

*1 As of March 2025

*2 As of September 2025



R&D Map (As of Nov. 1, 2025)



Strengthen R&D Capabilities

Yamanashi R&D building

Deposition system, gas chemical etch system, corporate R&D (Completed in July 2023)



Miyagi R&D building

Etch system (Completed in April 2025)



Kumamoto R&D building

Coater/Developers, surface preparation system, Bonder (Completed in October 2025)



Miyagi Technology Innovation Center

Etch system (Completed in September 2021)



TEL Digital Design Square

DX, Software (Began operation in November 2020)



Continually Pursuing the Best Products and Best Service







- Share roadmap for next several generations with customers
- Promote early engagement
- Realize maximum yield of customer devices and equipment availability from early stage of customers' mass production and reduce burden on the environment
- Further increase investment in human resources/R&D by raising operational efficiency and driving higher per-employee productivity

- Business development leveraging industry's largest installed base of 98,000 units*
- TELeMetrics[™] remote maintenance
- Predictive maintenance with machine learning

* As of September 2025



Maximize Utilization of TEL's Comprehensive Strengths

Sales

Customer trust

Marketing

Advanced data collection and analysis abilities

Broad product coverage











FS

- Largest installed base in industry: over 98,000 units*
- Advanced FS

* As of September 2025

R&D

- Strong next generation product development
- Process integration

Manufacturing

- High quality
- Robust supply chain

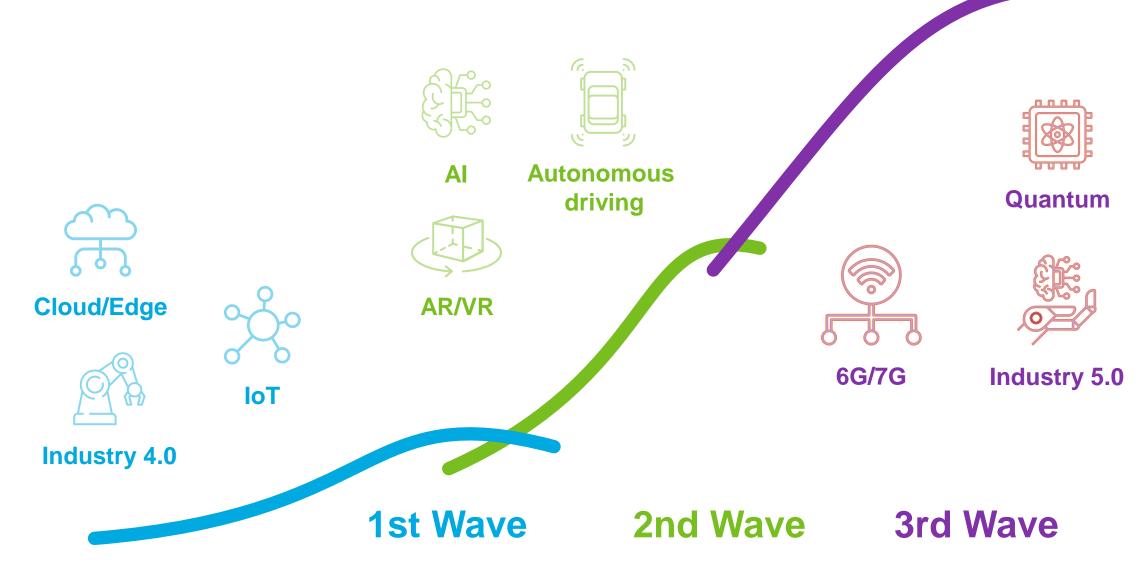
2. Semiconductor and SPE Market Outlook

Outlook for the Semiconductor Market (2030)**Autonomous** driving AR/VR **Industry 4.0 \$630.5** Billion Cloud/Edge (2024)IoT

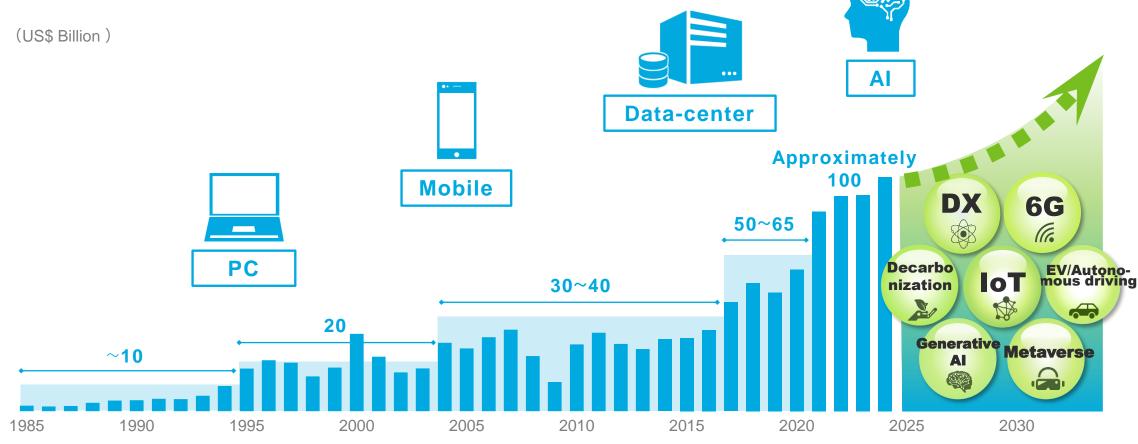
1st Wave

2nd Wave

Outlook for the Semiconductor Market



WFE* Market

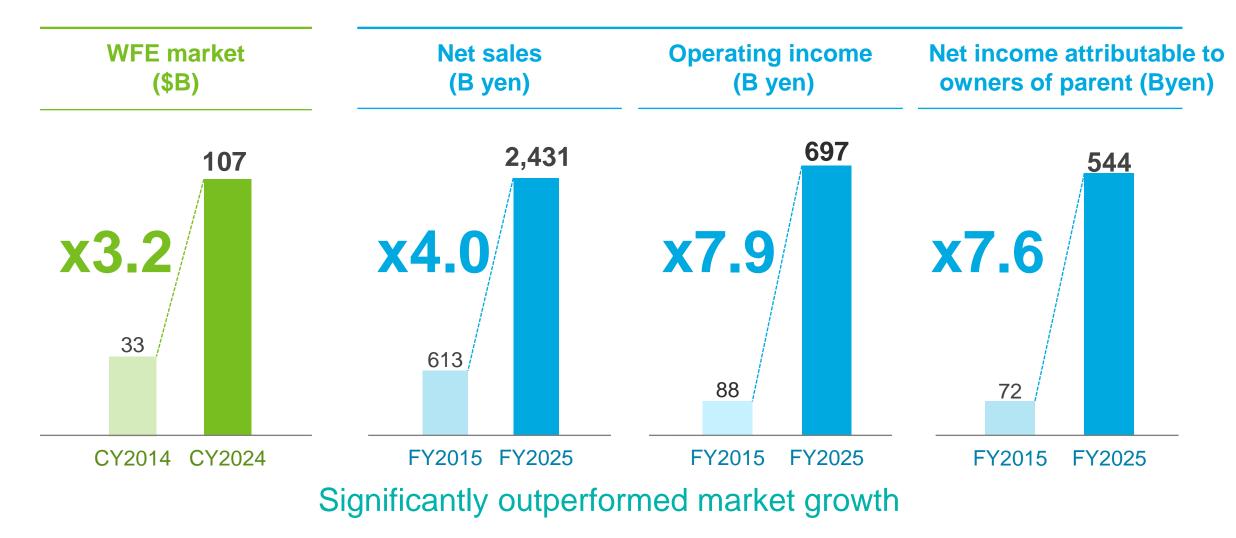


^{*} WFE (Wafer Fab Equipment): The semiconductor production process is divided into front-end production, in which circuits are formed on wafers and inspected, and back-end production, in which wafers are cut into chips, assembled and inspected again. WFE refers to the production equipment used in front-end production and in wafer-level packaging production.

Source : TechInsights Inc. (1985~2024)

WFE Market will grow further with progress of digitalization and evolution of semiconductors

Market and Performance Growth (FY2015 to FY2025)



Source: TechInsights Inc.

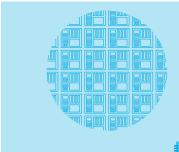
Green Future Through Semiconductor Evolution

Digital & Green-

Higher Speed

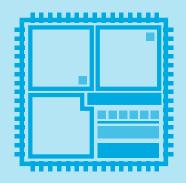
Larger Capacity Superior Reliability





Physical Scaling





Heterogeneous Integration

Physical Scaling x Heterogeneous Integration

Frontend

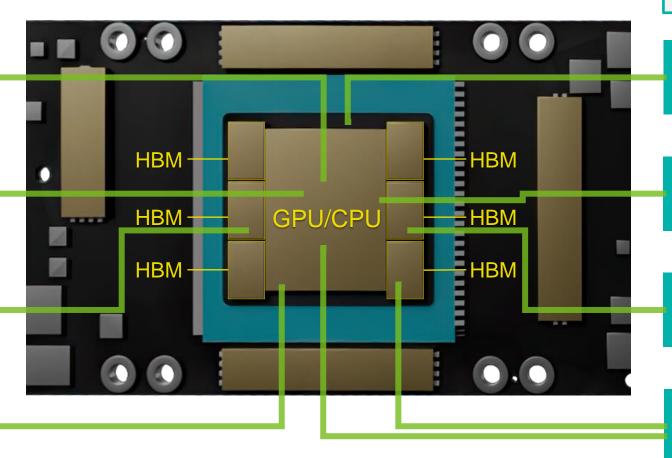
Logic
GAA * / CFET

Logic
Backside PDN *

DRAM4F² VCT * / 3D DRAM

Super Flat Wafer

Al Semiconductor



Advanced Packaging

Heat Spreader

3DIC Chiplet Integration

Stack Memory HBM, etc.

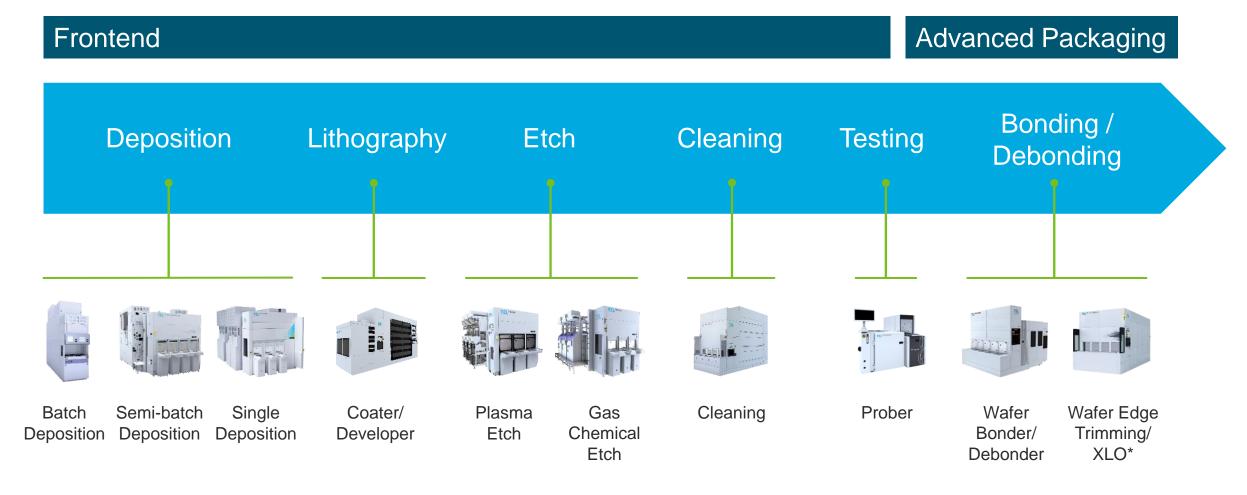
Known Good Die

* GAA: Gate All Around

^{*} Backside PDN: Backside Power Delivery Network

^{*} VCT : Vertical Channel Transistor

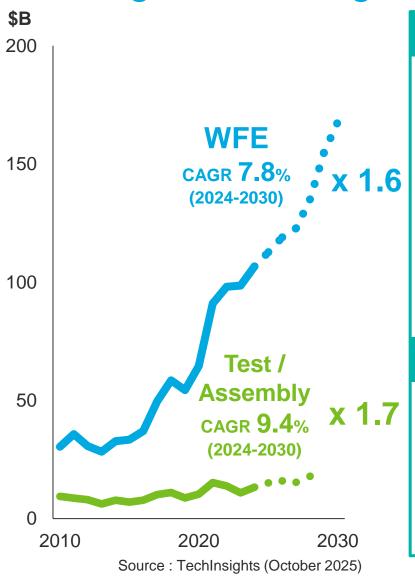
Expanding Opportunities: Wide Product Portfolio



*XLO: Extreme Laser Lift Off



Strategic Technologies for Future Growth



Frontend

Logic: GAA, BSPDN

- EUV Coater/Developer
- Gas Chemical Etch
- Conductor Etch
- PVD Metal Overburden
- CFET/Inner Spacer
 Plasma CVD for filling film
- Double-sided scrubber
- Backside/bevel cleaning
- Pattern Shaping
- Wafer Bonder
- Laser Tool

DRAM: 2D & 3D DRAM

- EUV Coater/Developer
- Capacitor Mold Etch
- Batch High-k Capacitor deposition
- PVD Metal Hardmask
- Supercritical Cleaning
- Backside/bevel Cleaning
- Wafer Bonder
- Laser Tool

NAND: Beyond 4xx

- Slit Etch
- Channel Hole Etch (Plug)
- Batch Mo deposition
- Batch Cleaning WL Separation
- Wafer Bonder
- Laser Tool

Advanced Packaging

Logic Packaging

- Interposer, Polyimide & PR Coater/Developer
- TDV Etch
- Batch High-k Capacitor depo
- Wafer Bonder
- Laser Tool

HBM Packaging

- Polyimide & PR Coater/Developer
- Metal Etch for HBM
- Aerosol Cleaning
- Temporary Bonder/Debonder

Advanced Logic / Memory Test

Prober



3. Corporate Principles and New Medium-term Management Plan

Corporate Principles System



Vision

A company filled with dreams and vitality that contributes to technological innovation in semiconductors

Tokyo Electron pursues technological innovation in semiconductors that supports the sustainable development of the world.

We aim for medium- to long-term profit expansion and continuous corporate value enhancement by utilizing our expertise to continuously create high value-added leading-edge equipment and technical services.

Our corporate growth is enabled by people, and our employees both create and fulfill company values. We work to realize this vision through engagement with our stakeholders.

Technology Enabling Life

"Technology Enabling Life" is our corporate message that expresses the Corporate Principles which consist of our Corporate Philosophy, Management Policies, Vision and TEL Values.

CSV

(Creating Shared Value)

The concept is to create social and economic value by leveraging corporate expertise to solve social issues, hereby enhancing corporate value and achieving sustainable growth.



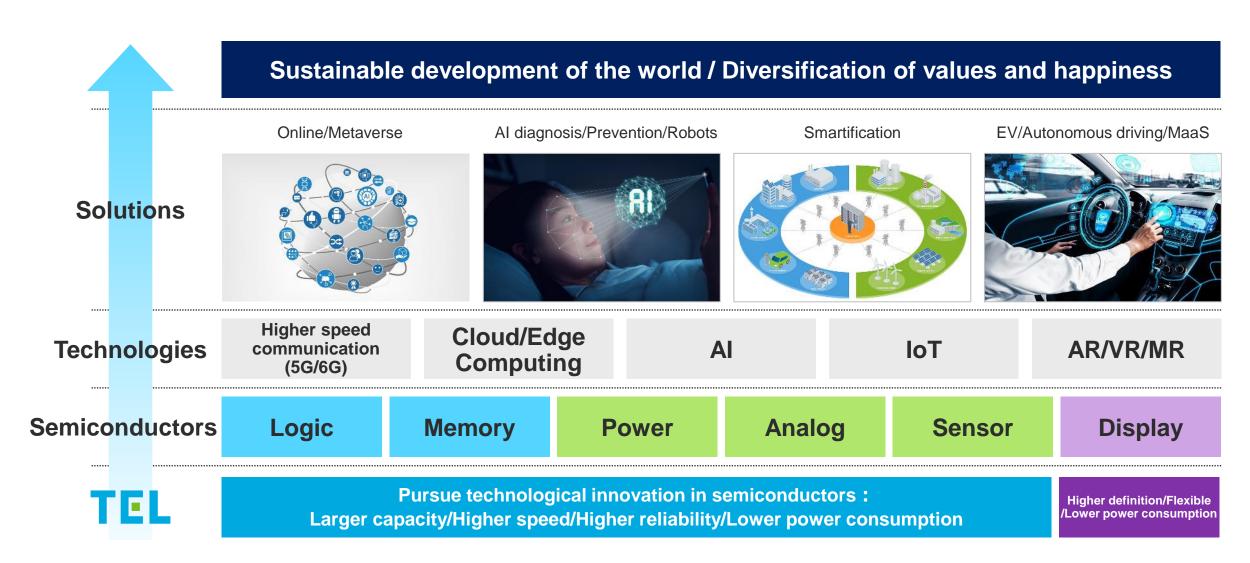


- Pursue technological innovation in semiconductors that supports the sustainable development of the world
- Continuously create high value-added leading-edge equipment and technical services
- Medium- to long-term profit expansion and continuous corporate value enhancement
- Engagement with our stakeholders

Realization of Vision = Creating Shared Value in TEL

TEL

Our Approaches to Social Issues



Vision & Medium-term Management Plan

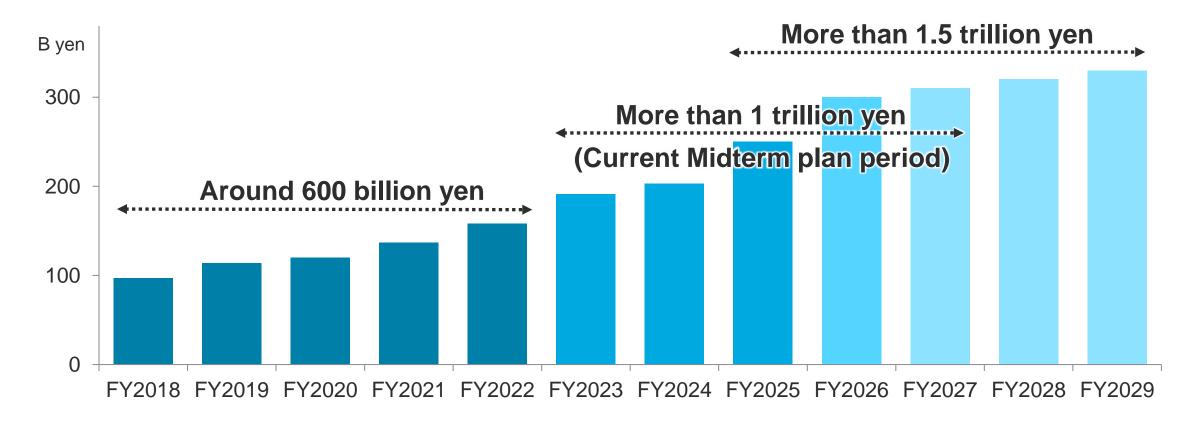
FY2023 FY2027 FY2031 (CY2030) Goals for 2030 Supporting sustainable development in the world 1 Driving the semiconductor market through technological innovation 2 Contributing to a sustainable global environment **Realization of Vision** Medium- to long-term profit expansion and continuous corporate value enhancement A company filled with dreams and vitality that contributes to technological **Engaging with our stakeholders** innovation in semiconductors Medium-term Management Plan (FY2023-2027) Achievement of Financial Model (Five-year goal toward 2030)

Aiming to achieve the Medium-term Management Plan by FY2027 with a view to realizing Vision in 2030

The New Medium-term Management Plan: Financial Targets

| Financial Targets (FY2023 - FY2027) | | |
|-------------------------------------|------------------|--|
| Net sales | ≥ 3 trillion yen | |
| OP margin | ≥ 35% | |
| ROE | ≥ 30% | |

Aggressive Investment in R&D



Driving the creation of high-value next-generation products through further growth investments

Investment for Growth Visioning beyond the Midterm Plan (FY2025 to FY2029)

R&D Investment

Capex

Recruitment

1.5 trillion yen



700 billion yen



10,000 people year



4. Business Environment and Financial Estimates

Market Environment (WFE Market Outlook as of October, 2025)

- CY2025 Forecast: Approx. \$115B No changes
 - Investments are primarily being driven by leading-edge logic and DRAM for AI applications
 - NAND is showing signs of recovery, investment in mature nodes remains subdued
- Looking ahead, expecting continued expansion in investments for leadingedge semiconductors, fueled by strong demand for AI servers
 - DRAM: Investment surging for both HBM and general-purpose DRAM.
 Double-digit growth is anticipated to continue in the following years
 - NAND: Rising SSD-demand boosts utilization and drives investment growth
 - Logic/foundry: Investment in leading-edge nodes accelerates, with progress in advanced packaging
 - Mature nodes: WFE spending is expected to remain roughly flat at current levels

Demand for high-value-added equipment expected to grow from next year

Growing Opportunities: Scaling x Heterogeneous Integration

Etch

>500 B yen

DRAM Etchers for Interconnect:

Growth driven by increased investment in HBM with more interconnect layers

Cumulative sales over 500 billion yen expected by 2030

Bonder Laser

>500 B yen

3D Integration Equipment including Bonders:
 Rapid expansion across all applications

Cumulative sales over 500 billion yen expected by 2030

Prober

CAGR >15%

Probers for AI/HPC:

Driven by longer test times and more process steps, projecting CAGR over 15% (CY2025-CY2030)

Die Prober PECVD

SAM +10% Die Probers:

Development and evaluation agreed with customers Creating 10-15% of the prober market SAM

 PECVD for Gap Fill: SAM estimated to be approx. 10% of PECVD market Evaluations progressing with multiple customers

Financial Estimates for FY2026

(Billion Yen)

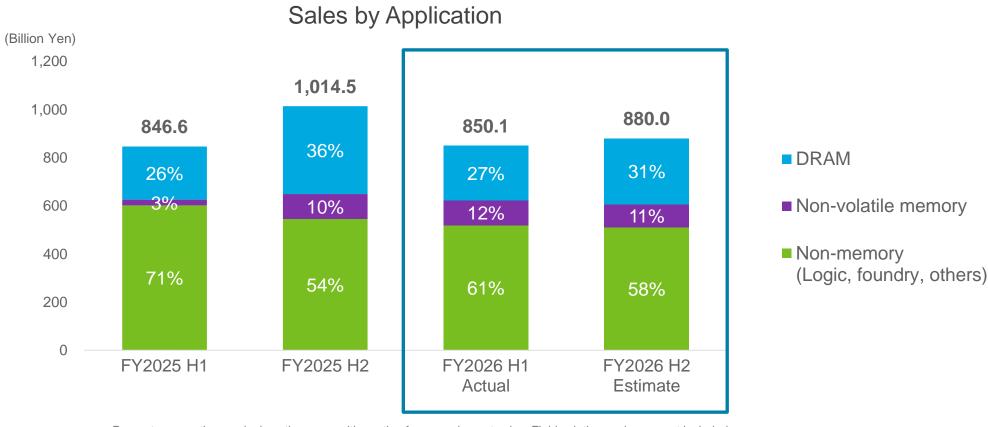
| | FY2025 | | | Reference: FY2026 (Estimate as of July 31) | | | | |
|---|-------------------------|-------------------------|-------------------------|---|--------------------------|---------------------|-------------------------|-------------------------|
| | (Actual) | H1 (Actual) | H2 (Updated) | Full Year (Updated) | vs FY2025 | Adjustments* | H2 | Full Year |
| Net sales | 2,431.5 | 1,179.6 | 1,200.3 | 2,380.0 | -2.1% | 30.0 | 1,200.0 | 2,350.0 |
| Gross profit Gross profit margin | 1,146.2 47.1% | 538.8 45.7% | 540.1 45.0% | 1,079.0 45.3% | -5.9% -1.8pts | 13.0 -0.1 pts | 539.0 44.9% | 1,066.0 45.4% |
| SG&A expenses R&D Other than R&D | 448.9 250.0 198.9 | 235.7 134.8 100.9 | 257.2 155.1 102.1 | 493.0 290.0 203.0 | +9.8% +16.0% +2.1% | -3.0 -5.0 2.0 | 257.0 155.0 102.0 | 496.0 295.0 201.0 |
| Operating income Operating margin | 697.3 28.7% | 303.1 25.7% | 282.8 23.6% | 586.0 24.6% | -16.0% -4.1pts | 16.0 0.4pts | 282.0 23.5% | 570.0 24.3% |
| Income before income taxes | 706.1 | 312.9 | 322.0 | 635.0 | -10.1% | 56.0 | 286.0 | 579.0 |
| Net income attributable to owners of parent | 544.1 | 241.6 | 246.3 | 488.0 | -10.3% | 44.0 | 220.0 | 444.0 |
| Net income per share (Yen) | 1,182.40 | 527.31 | - | 1,064.77 | -117.63 | 95.65 | - | 969.12 |

^{*} Changes from the figures announced on July 31, 2025

Full-year outlook revised based on H1 results.
Reflected extraordinary income from sales of strategic shareholdings

Investor Relations / November 7, 2025

FY2026 SPE New Equipment Sales Forecast



Percentages on the graph show the composition ratio of new equipment sales. Field solutions sales are not included.

Updated application mix based on latest outlook



FY2026 R&D Expenses and Capex Plan

Development Building No. 3 Etch system



Kurokawa-gun, Miyagi Prefecture
Completed in April 2025

Tohoku Production and Logistics Center

Deposition system



Oshu-city, Iwate Prefecture
Completion scheduled for autumn 2025

Process Development Building

Coater/developer, cleaning system



Koshi-city, Kumamoto Prefecture Completed in October 2025

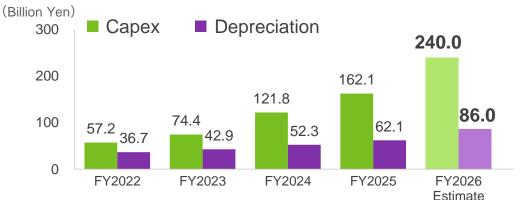
Miyagi Innovative Production Center

Etch system



Kurokawa-gun, Miyagi Prefecture
Completion scheduled for summer 2027



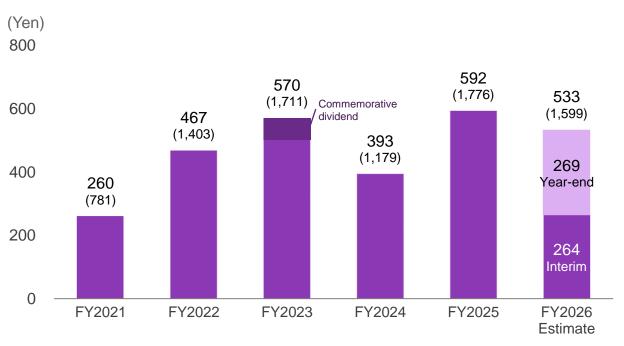


Semiconductors for AI servers drive technology innovation, fueling expanding demand.

R&D and capital investments to proceed as scheduled

FY2026 Dividend Forecast

Dividend per Share



TEL shareholder return policy

Dividend payout ratio: 50%

Annual DPS of not less than 50 yen*

We will review our dividend policy if the company does not generate net income for two consecutive fiscal years

We will flexibly consider share buybacks

*Due to the stock split on April 1, 2023, the amount has been changed from 150 yen to 50 yen.

- Dividends per share from FY2021 to FY2023 are calculated on the assumption that the stock split was conducted at the beginning of FY2021.
- FY2023 includes the 60th anniversary commemorative dividends.
- Amounts before the stock split are shown in parentheses.

Full-year dividends are expected to be 533 yen per share



5. Sustainability

Sustainability Initiatives

The 14 material issues (key issues) that require prioritized attention and actions are identified to implement sustainability initiatives through our business operation and contribute to the resolution of industrial and social issues.





Respect for Human Rights



Climate Change and Net Zero



Product Energy Efficiency



Best Products with Innovative Technology



Best Technical Service with High Added Value



Customer Satisfaction and Trust



Supplier Relationship



Employee Engagement



Safety First Operation



Quality Management



Compliance



Ethical Behavior



Information Security



Enterprise Risk Management





Risk Management System and Implementation

System

- Established the Corporate Project & Risk Management Office (CPRO) in the Corporate Strategy Division at the head office to promote more effective risk management in the Group as a whole, while actively working toward advancing enterprise risk management*1
- The Group's risk management activities are regularly reported to the Board of Directors, which oversees various initiatives implemented by each risk owner
- To raise awareness of risk management and provide basic knowledge, we regularly conduct web-based training on risk management for our Group employees and training programs for managers.

Implementation of the PDCA cycle

To address major risks*2 in our business activities, we have implemented the following PDCA cycle throughout the entire Group.

By reviewing and revising the major risks, we push risk management initiatives forward for each identified risk even further.



^{*1} Enterprise risk management: Group-wide systems and processes related to risk management activities



^{*2} Major risks: For details on identifying risk items and each risk item, please refer to the "Risk Management" section of our website https://www.tel.com/sustainability/management-foundation/risk-management/index.html

Environmental Approaches



Scope 1, 2 & 3 Achieve Net Zero by Fiscal 2041

Scope 1, 2: CO2 emissions from energy use such as electricity in business activities

Scope 3 : CO2 emissions from the use and disposal of sold equipment, material purchases and logistics, etc.





Semiconductors

Pursuing higher device performance and lower power consumption



Products

Achieving both high process performance and environmental performance of the equipment



Business activities

Reduction of CO₂ emissions in all business activities

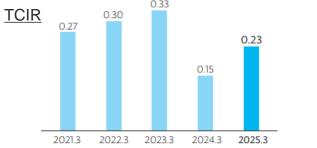


Promoting technological innovation of semiconductors and reducing environmental impact throughout the supply chain

Safety & Quality

Safety

Under the "Safety First" slogan, everyone at Tokyo Electron, from top management to field representative, is actively and continuously improving safety and promoting health, giving safety and health the highest priority when carrying out different types of operations such as development, manufacturing, transportation, installation and maintenance.



Safety Goals (by FY2027) TCIR ≤ 0.1

In fiscal 2025, through enhancement of safety training and continuous efforts toward safe design of equipment, we achieved a TCIR of 0.23, an industry-leading position in the semiconductor production equipment industry.

TCIR: Total Case Incident Rate (Number of workplace injuries per 200,000 work hours)

Incident Prevention Initiatives

- Experiential training and VR (Virtual Reality)
- Comprehensive safety inspections
- Feedback on safety specifications
- Safety activities for suppliers



Quality

The Tokyo Electron Group seeks to provide the highest-quality products and services. This pursuit of quality begins at development and continues through all manufacturing, installation, maintenance, sales and support processes. Our employees must work to deliver quality products, quality services and innovative solutions that enable customer success.



TEL Values as codes of conduct



Engagement



Career



Corporate growth is enabled by People, and our employees both create and fulfill company values

Retention



Work-life balance



Diversity, Equity and Inclusion



Global · Generation · Gender

Human Rights Initiatives

The five focus areas in human rights (Tokyo Electron Group Human Rights Policy)

Freedom, equality & non-discrimination

Freely chosen employment

Product safety & workplace health and safety

Freedom of association Appropriate working hours & breaks/ holidays/vacations

Human Rights Due Diligence









Commitment

Commitment to respecting

human rights

Group Human Rights Policy

Awareness and implementation

Revision of Tokyo Electron

Assessment of human rights risks

Assessment

in business and supply chains

- Human rights risk assessment
- Human rights impact assessment

Remediation

Actions to reduce risks based on assessment results

- Feedback sheet publication
- Program development and review according to issues

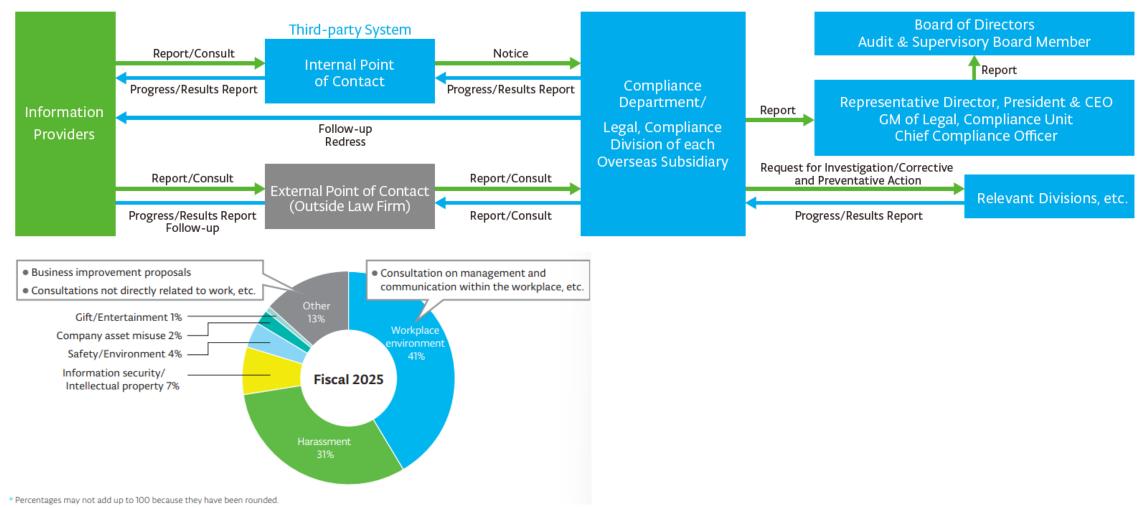
Report

Regular disclosure of information

- Publication of the Integrated Report
- Postings on the website

Education

Internal Reporting System

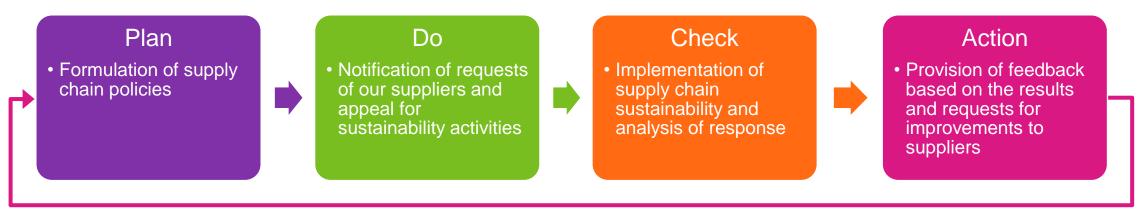


Respect for human rights with a strong sense of integrity



Supply Chain Management

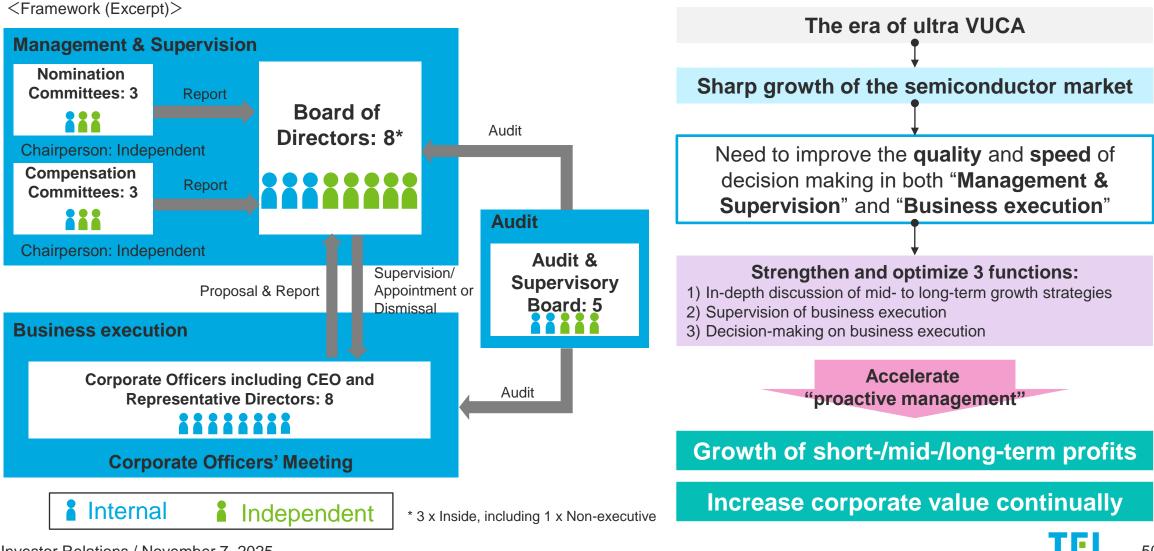
Supply chain sustainability process



- Annual Sustainability Assessment
 - Assessment base on RBA code of conduct
 - Corrective Action Plans
- RBA Audit
 - At primary manufacturing sites
 - Continuous improvement in respective operations

Pursuit of sustainability conscious operations throughout the supply chain

Corporate Governance Framework (Audit & Supervisory Board System)



Evaluation of the Effectiveness of the Board of Directors

Survey administered to all corporate directors and Audit & Supervisory Board members

Interviews of all corporate directors and Audit & Supervisory Board members by external experts

Report by external experts

Deliberations at internal meetings

Meetings for exchanges of opinions by independent directors and independent Audit & Supervisory Board members

Discussion and self-evaluation by the Board of Directors

Internal and external experts analyze and evaluate the effectiveness of the Board of Directors

Global Initiatives

Sustainable Development Goals (SDGs)

Clarify initiatives through business by materiality and deploy company-wide

SUSTAINABLE GALS





8 働きがいも 経済成長も























Tokyo Electron supports the SDGs

Participation in International Initiatives

Signed the UN Global Compact, joined the Responsible Business Alliance (RBA), endorsed the Task Force on Climate-related Financial Disclosures (TCFD)







External Evaluation on our ESG Initiatives

Highly rated by evaluation organizations around the world

Dow Jones Best-in-Class Asia Pacific Index





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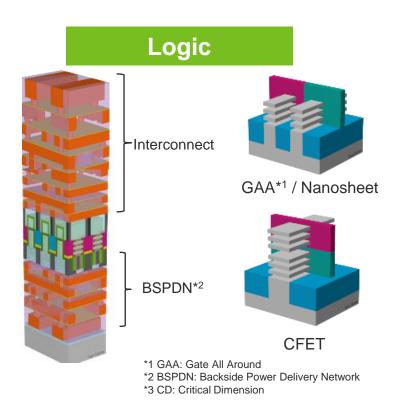


6. Diversifying Semiconductor Technology

~ Technology Roadmap~

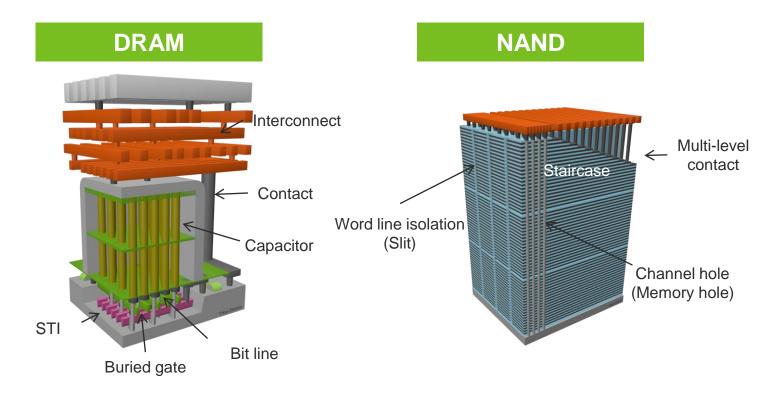


Semiconductor Devices: Direction of Development



Through miniaturization with structural changes

- Lowered cost per transistor
- Lower power consumption
- Higher speed



Through miniaturization

- Lower cost per bit
- Lower power consumption
- Higher speed

Through new structures

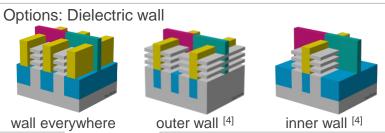
Lower cost per bit

Through high stacking

Lower cost per bit



Logic Technology Roadmap



 $^{\mbox{\scriptsize [1]}}$ Chih-Hao Chang (TSMC) et al., IEDM 2022

[2] Shien-Yang Wu (TSMC) et al., IEDM 2022

[3] Sandy Liao (TSMC) et al., IEDM 2024 [4] Mertens and Horiguchi (imec), EDTM 2024

Source: TEL estimates

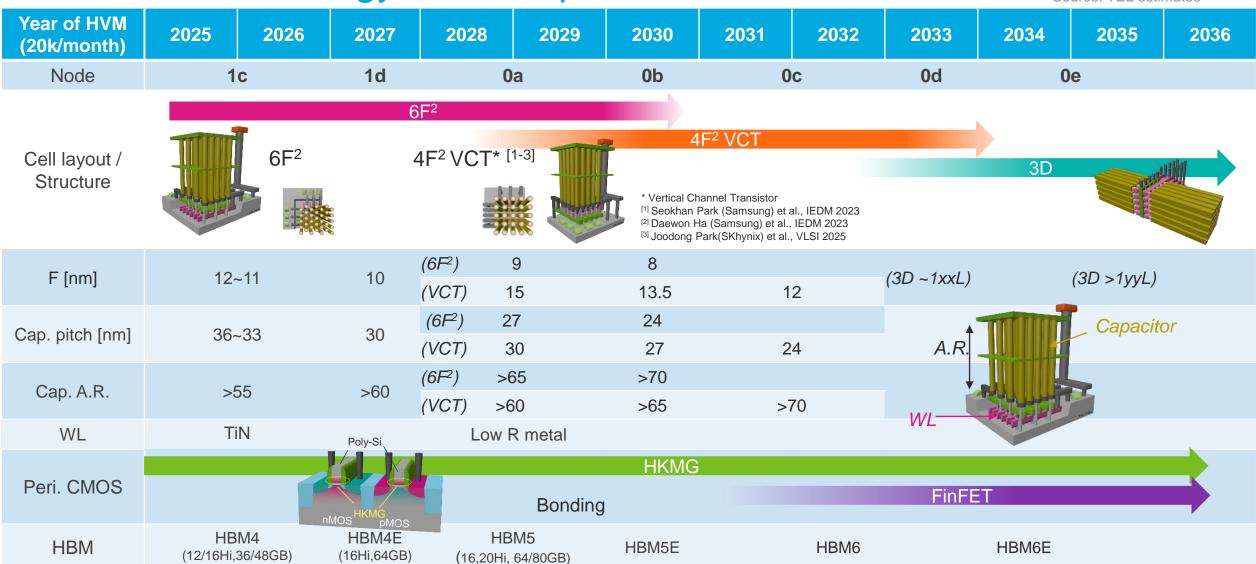
| Year of HVM (20k/month) | 2022~24 | 2025~2026 | 2027~28 | 2030~31 | 2033~34 | 2036~37 | 2039 an | d beyond | | |
|------------------------------|---|-------------|-----------------------------|-----------------------------|---|------------------------------|---------------------------|--|--|--|
| Node | 3nm | 2nm/18A/16A | 14A | 10A | 7A | 5A | 3A | 2A | | |
| Transistor | 2~1 Fin | GAA NS | GAA NS scalin | g GAA NS extension | CFET | 2 nd Gen. CFET | 3 rd Gen. CFET | 2D material stack IL/HK IL/HK 2D material: TMDC MoS ₂ , WS ₂ , MoSe ₂ , WSe ₂ etc. | | |
| Poly Pitch [nm] | 48~45 ^[1] | | 45~42 48 ^[3] ~42 | | 45 | ~39 | 36 | | | |
| Min. Metal Pitch [nm] | 23 [2] | | 20 | 18 | 17 | 16 | 14 | 12 | | |
| Interconnect booster | Cu Barrier/Seed CIP Backside PDN (HPC) | | Cu CIP or Ru subtractive | Ru subtractive AR>3, Airgap | New alloy AR>5, Airgap, BEOL Transistor (OS*5, 2D material) | | O 1 · | | | |
| EUV Patterning Technology | EUV MP*1, SE*2 | | • | EUV MP, SE High-NA SE | | High-NA MP, SE EUV MP, SE | | | | |
| Resist | CAR*3 | | | CAR (+MOR*4) | CAR (+MOR*4) | | | CAR+MOR | | |

*1 MP: Multi-Patterning, *2 SE: Single-Exposure, *3 CAR: Chemically Amplified Resist, *4 MOR: Metal Oxide Resist, *5 OS: Oxide Semiconductor

Logic scaling will continue by changing transistor structure and material evolution

DRAM Technology Roadmap

Source: TEL estimates



NAND Technology Roadmap

| | | | 3) | | | | | | | Sou | irce: TEL estin | nates |
|----------------------------|----------------------|----------|------|-------------------------------------|--------------------|---------|----------------|--|--------------|----------------------------|-----------------|-------------------|
| Year of HVM (20k/month) | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 | 2032 | 2033 | 2034 | 2035 | 2036 |
| Stack (~1.3x/1.5years) | 3xxL | 4x | xL | 5xxL | 7x: | xL | 1xxxL | *1y | yyL | *1zzzL | *2x | xxL |
| Tier | 2 or 3 | (| 3 | 3 or 4 | 3 - | 6 | 4 - 8 | | | | | |
| Vertical pitch [nm] | 39 - 46 | 38 | - 43 | 38 - 42 | 37 - | 41 | 36 - 40 | 35 | - 39 | 34 - 38 | 33 - | - 37 |
| Memory height [μm] | 12 - 15 | 16 | - 18 | 19 - 25 | 20 - | 40 Poly | 35 - 45 | 45 | - 62 | 57 - 74 Ferroelectric | | - 84 Resistive |
| Charge trap (CT) | Continuo | ous CT | | | CT is | olation | | | | Fe/Re NAND ³ | | |
| Channel | Poly Si g | rain CIP | | MILC ¹ /MIC ² | 2 | TiN/W — | | Мо | | | | |
| WL metal | W or M | 0 | | Мо | | | | OT in alation | | | | |
| Layout/Structure | Under ar or Bondi | • | | Bonding | Bond or Multi I | 0 | | CT isolation#of memory hole | es b/w slits | | FeNAND | ReNAND |
| Peri. CMOS | Poly Si (| Gate | | | Hk | KMG | Vertical Pitch | - | | | | |

^{*}Trend Extrapolation



Bonding

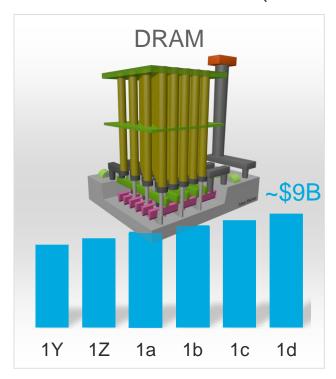
¹ Metal induced lateral crystallization

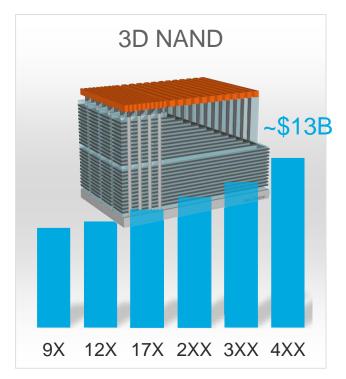
² Metal induced crystallization

³ 2023 IEDM Fundamental Issues in VNAND Integration Toward More Than 1K Layers - Samsung

Raising Added-value in SPE

WFE investment (100k WSPM*, Greenfield/TEL estimates)





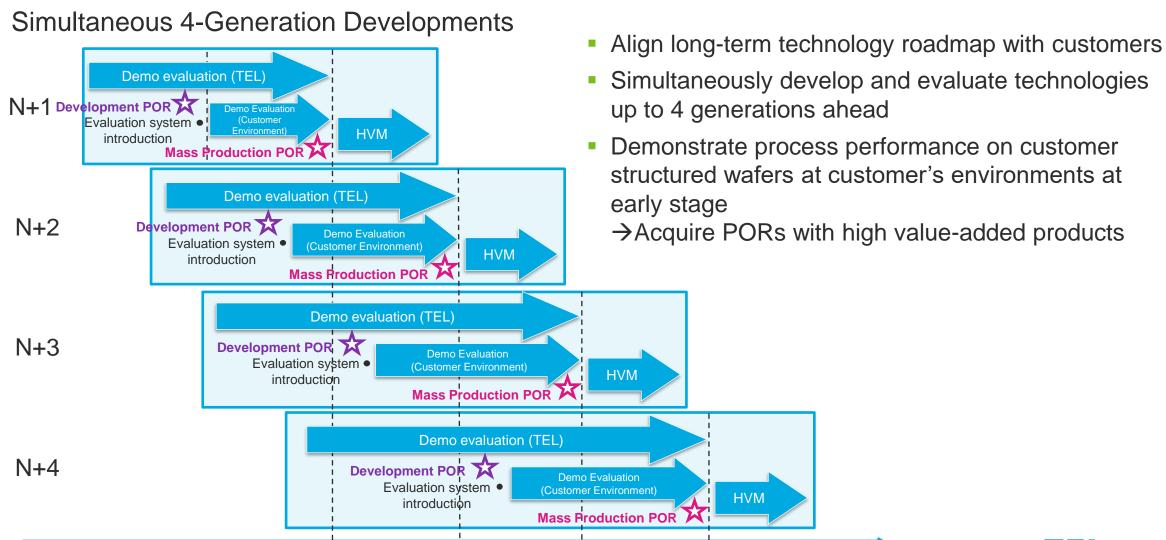


Expanding business opportunities for SPE manufacturers on arrival of new applications and rising level of technological difficulty

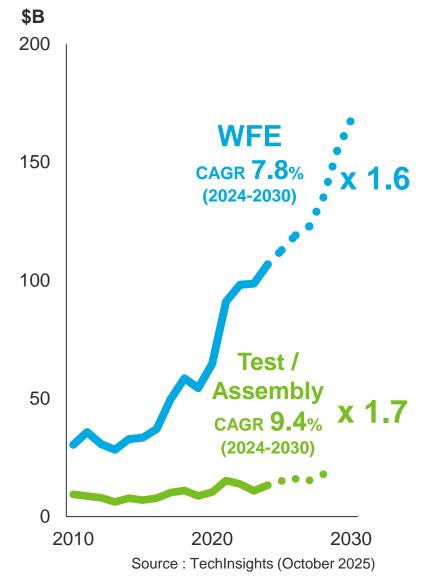
7. SPE New Equipment Initiatives



Development Efforts



Our Growth Opportunities in the Frontend Market



- CAGR driven by AI-related devices to continue to drive high growth of WFE's CAGR
- Leveraging TEL's strengths to address high-growth market areas:
 - Leading-edge logic: The etch market is expected to grow by 2.7 times, the deposition market by 2.5 times*
 - DRAM: The etch market is expected to grow by 2.3 times, exceeding the CAGR of WFE*
- By introducing new products focused on the key technological inflection points, we aim to further expand our areas of entry

* TEL Estimates



Growth opportunities at Technological Inflection Points in Frontend Process

Logic: GAA*1, BSPDN*2, CFET

- Adaption of High-NA lithography, combined with multi-patterning and MOR technologies, presents opportunities for new technology Acrevia™
- Adoption of multi-patterning to increase demand for deposition, etch, and cleaning processes.
- GAA and CFET transistors to drive an increase in gas chemical etch processes
- New materials like ruthenium and structural innovations such as air gaps to generate fresh opportunities

DRAM: HBM, VCT*3, 3D DRAM

- Adoption of multi-patterning driving increased demands in deposition and etch
- Capacitor formation remains essential, driving ongoing demand for advanced etch and deposition
- 3D DRAM leading to increased processes in deposition, etch and gas chemical etch

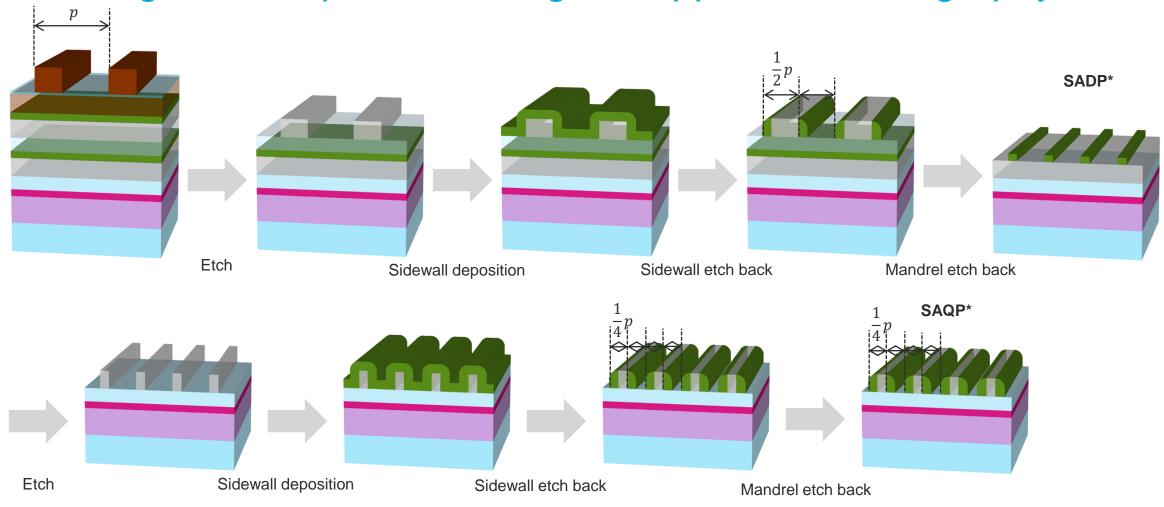
NAND: Beyond 4xx

- Increased layer counts leading to higher investments in deposition and etching processes
- High aspect ratio etch to become increasingly important
- New materials such as molybdenum, and low-resistance channel silicon to be utilized



7-1. Frontend, Patterning Technologies

Self-aligned Multiple Patterning to Supplement Lithography



SADP: Self-aligned double patterning SAQP: Self-aligned quadruple patterning

EUV Lithography Technology Roadmap in Logic

 $^{\text{[1]}}$ Chih-Hao Chang (TSMC) et al., IEDM 2022

[2] Shien-Yang Wu (TSMC) et al., IEDM 2022

[3] Sandy Liao (TSMC) et al., IEDM 2024

[4] Mertens and Horiguchi (imec), EDTM 2024

Source: TEL estimates

| Year of HVM (20k/month) | 2022~24 | 2025~2026 | 2027~28 | 2030~31 | 2033~34 | 2036~37 | 2039 an | d beyond |
|------------------------------|---------|-------------------|----------------|------------------------|------------|---------------------------|-----------------------------|--|
| Node | 3nm | 2nm/18A/16A | 14A | 10A | 7A | 5A | 3A | 2A |
| Transistor | 2~1 Fin | GAA NS | GAA NS scaling | GAA NS extension | CFET | 2 nd Gen. CFET | 3 rd Gen. CFET | 2D material stack IL/HK IL/HK 2D material: TMDC MoS ₂ , WS ₂ , MoSe ₂ , WSe ₂ etc. |
| Poly Pitch [nm] | 48~ | 45 ^[1] | 45 | 5~42 | 48 [3] ~42 | 45 | ~39 | 36 |
| Min. Metal Pitch [nm] | 23 | 3 [2] | 20 | 18 | 17 | 16 | 14 | 12 |
| EUV Patterning Technology | EU | V MP*1, SE*2 | | EUV MP, S High-NA S | | | High-NA MP, S EUV MP, SE | E |
| Resist | | CAR*3 | | CAR (+MOR*4) | | CAR- | +MOR | |

*1 MP: Multi-Patterning, *2 SE: Single-Exposure, *3 CAR: Chemically Amplified Resist, *4 MOR: Metal Oxide Resist

Enhancing versatility of coater/developer to respond to future EUV lithography technologies including MOR and high-NA EUV

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Coater/Developer: CLEAN TRACK™ LITHIUS Pro™ Z for EUV

LITHIUS Pro[™] Z released in 2012 (> 3000 systems shipped)

New features to support EUV CAR*1/MOR*2 to be released as on an ongoing basis

High Reliability

High share in EUV market

High Productivity

Maximizes output of EUV lithography tools, and reduces chemical consumption

High Versatility

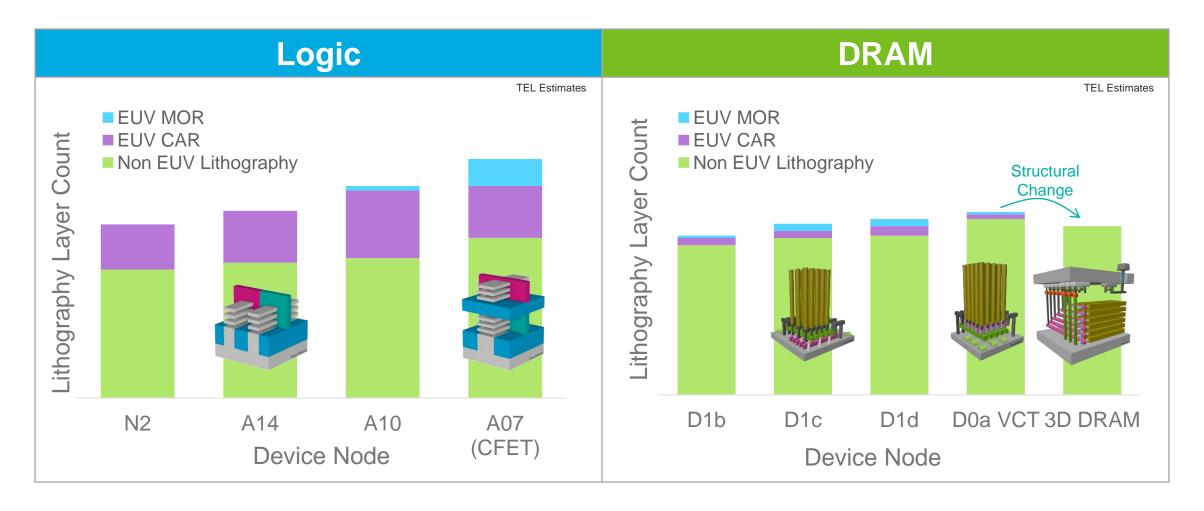
Supports CAR, MOR and underlayers



*1 CAR: Chemically Amplified Resist *2 MOR: Metal Oxide Resist

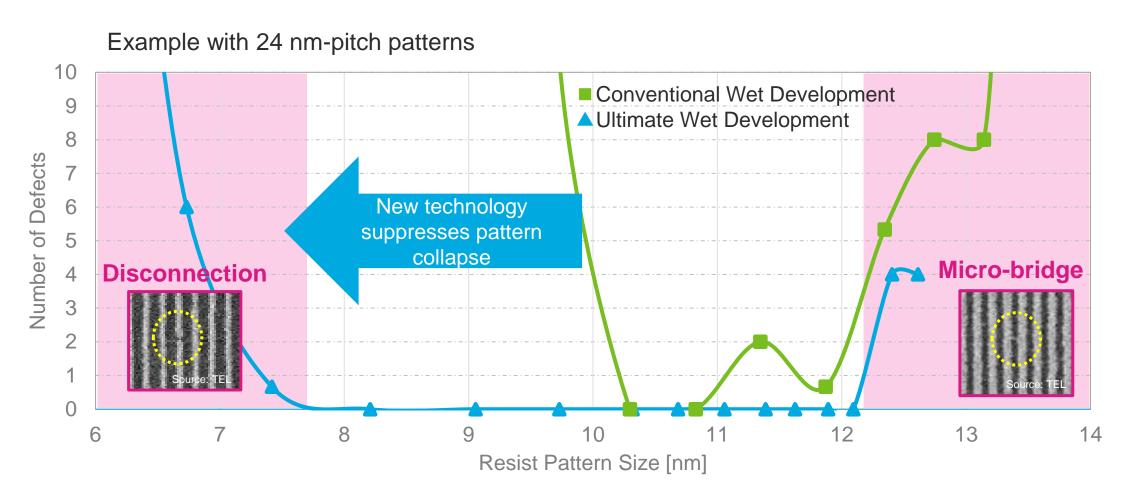
LITHIUS Pro™ Z platform with its proven mass production for various litho tools, ensures high reliability and productivity for EUV litho, along with high versatility for next-generation EUV

Outlook on Lithography Layer Count



MOR expected for Logic 10A/ DRAM D1b, development ongoing for MOR

Example of MOR Process: The Ultimate Wet Development



The Ultimate Development technology enables the suppression of pattern collapse

Example of MOR Solution: The Ultimate Wet Development

*1 Based on internal information and development targets
*2 Based on results of developing 24 nm-pitch lines

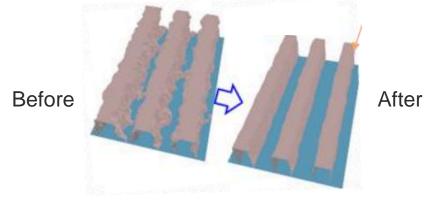
| | Ultimate Wet Development Technology | Conventional Wet Technology | Alternative Technology |
|-------------------------------------|---|--------------------------------|---|
| Base Technology | Coater/Developer | Coater/Developer | Etch |
| Process Ambient | Atmospheric | Atmospheric | Vacuum |
| Reaction | Chemicals | Chemicals | Corrosive Gas |
| Throughput*1 | 4x | 4x | 1x |
| Chemical Consumption*1 | 50% (vs. conventional) | 100 % | N/A (uses gas) exhaust processed in combustion abatement post process |
| Anti-Pattern Collapse*1 Performance | < 8 nm* ² | > 10 nm* ² | < 8 nm*1 |
| Footprint*1 | In-Line | In-line | Additional Footprint |

Evaluation of Ultimate Wet Development ongoing with key customers, with emphasis on productivity (throughput, footprint, maintainability, utilize existing facilities)

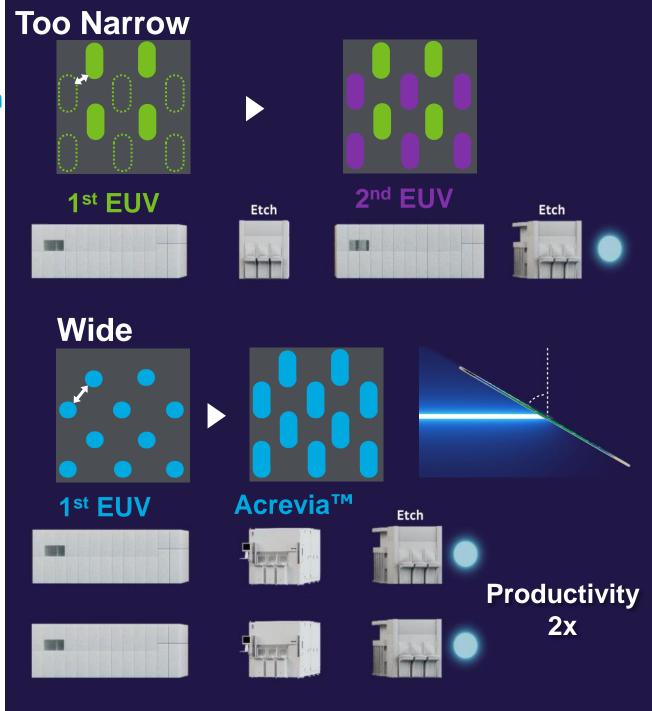
Acrevia™

TEL's Original Gas Cluster Beam (GCB) System

- Beam Angle is freely Adjustable
- LSP (Location Specific Processing) Wafer Scan
 - → Enable 3 Dimetional Etching
- Drastically Improve EUV productivity
 by EUV step reduction with fine patterning
- ✓ Realize yield by removing defect between pattern and improving LER/LWR*



* LER/LWR: Line Edge Roughness / Line Width Roughness



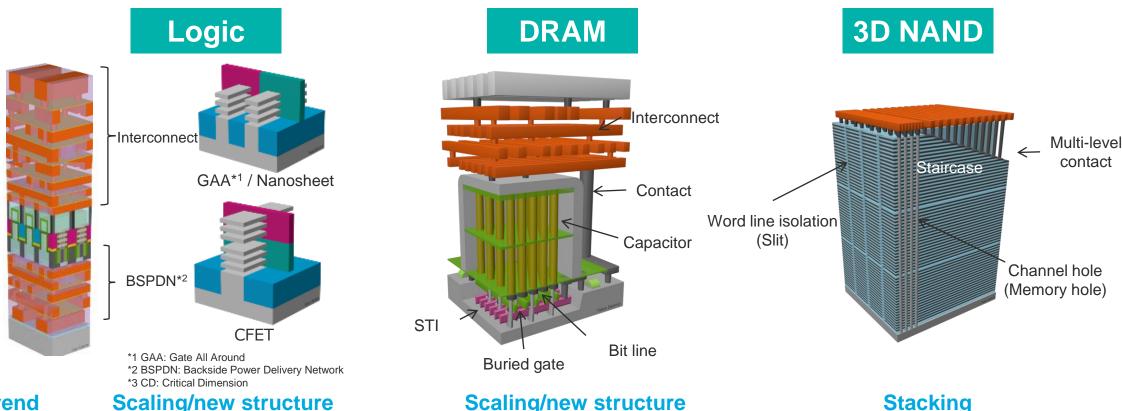
7-2. Frontend, Unit Process



7-2-1. Etch System



Requirements and Various Etch Technologies



Device trend

Technology Required

High selectivity through precise ion control Low-damage process Profile control (vertical, etc.)

Scaling/new structure

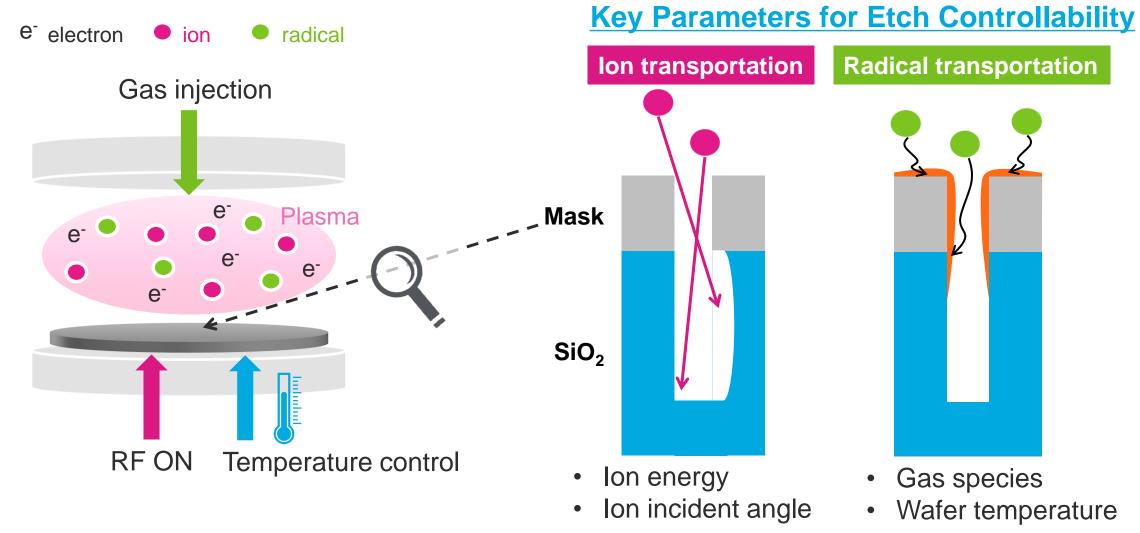
Small CD*3, high aspect ratio capacitor etch Scaled mask etch (EUV, multi patterning) HBM (increase in interconnect, etc.)

Stacking

Fast and vertical high aspect ratio etch Depth monitoring and process control Within wafer uniformity control

Etch technology with precise controllability is required for further evolution of devices

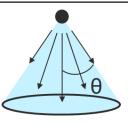
Overview of Etching and Key Parameters



Our Unique Technology 1: HERB™

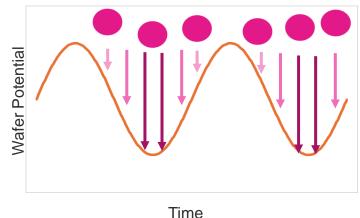
Ion transportation Mask SiO₂

Conventional Technology (Sine wave)



The force attracting ions varies

→incident angle varies

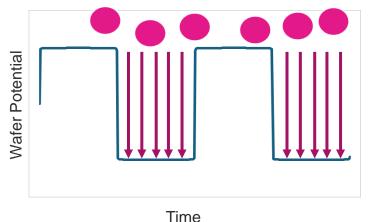


(HERB™: <u>High Efficiency Rectangular Bias™</u>)

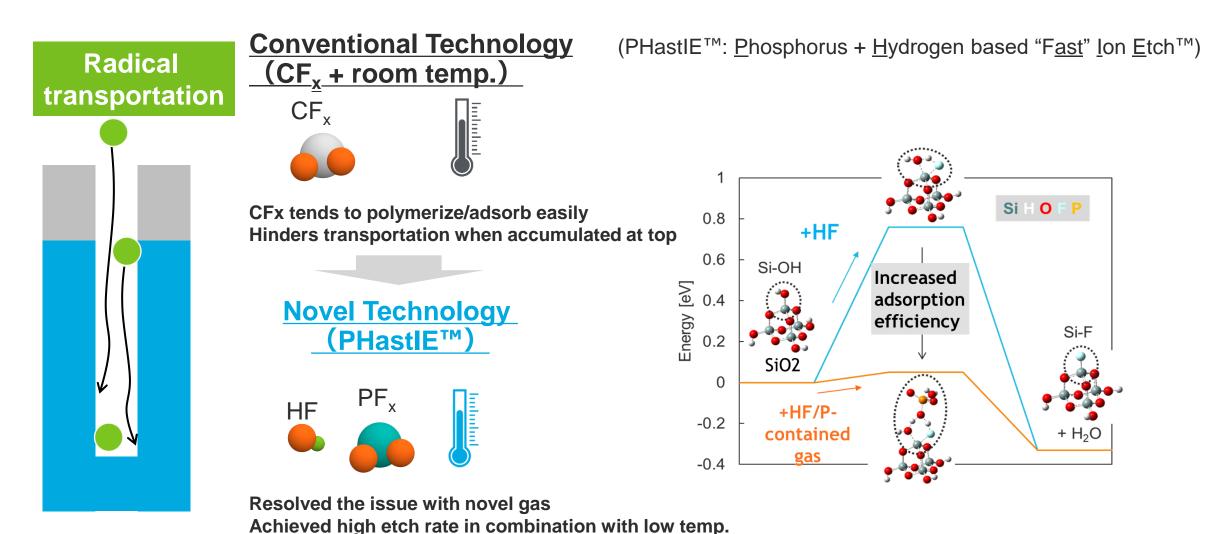


Force attracting ions are strong and consistent

→incidence angle becomes perpendicular



Our Unique Technology 2: PHastIE™



Novel Cryogenic HARC Etch



Beyond



Process

Cryogenic temp.

More Linear, Deeper & Faster

Plasma Control

Deep-learning Optimization

Environment

Power Consumption

Less Power

CO₂e

-83%

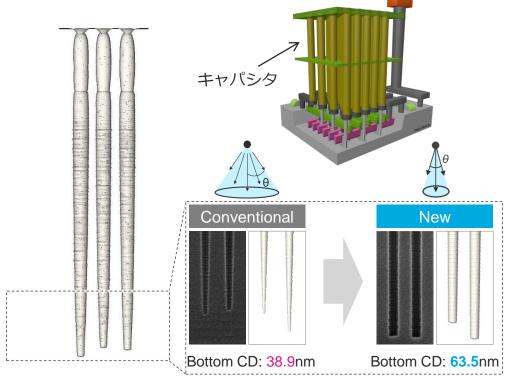
-43%

Less Carbon Footprint

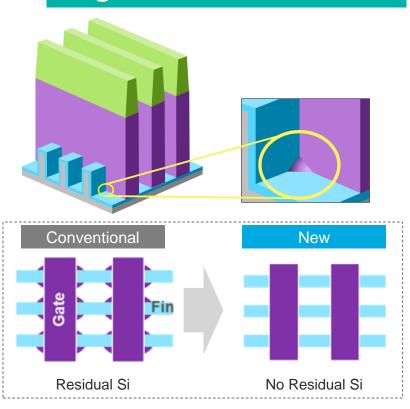
Presented world's first new cryogenic process in 2023 (@VLSI 2023), achieving both high process and environmental performance

Future of New Etch Technologies

DRAM: Capacitor SiO₂ Etch

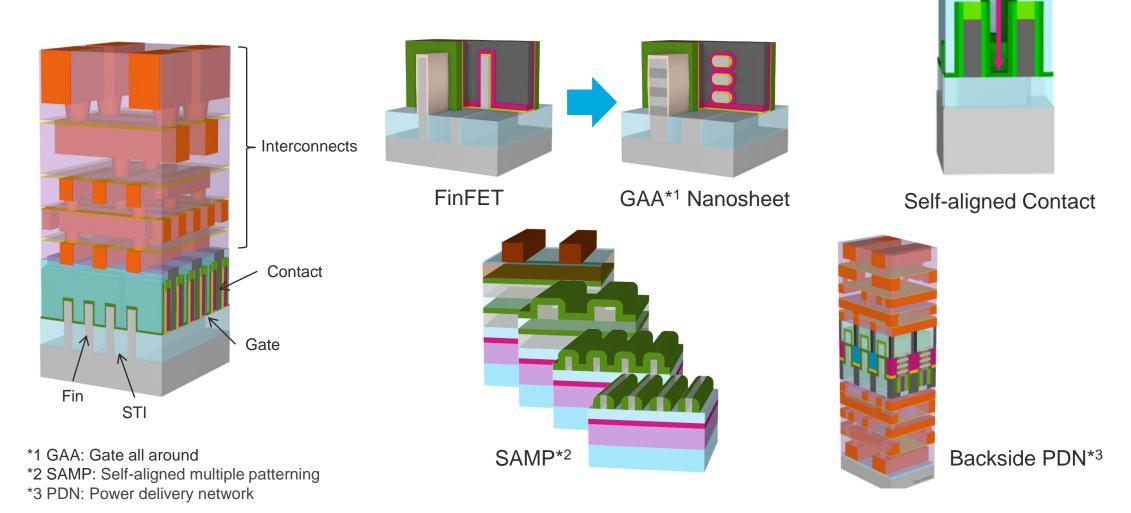


Logic: Gate Silicon Etch



New technologies created through the development of ideal etching process development, will be applied to a variety of critical processes

Business Opportunities in Logic



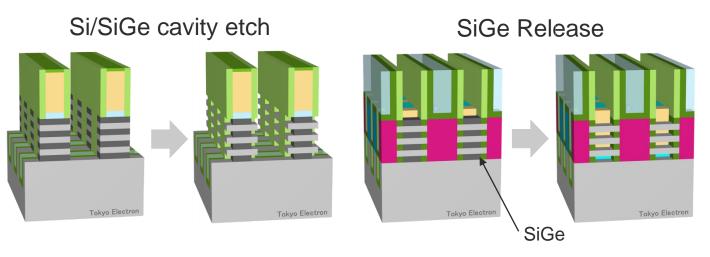
Respond to changes in device manufacturing and EUV lithography for further scaling

TEL

Initiative for GAA Nano Sheet Structures

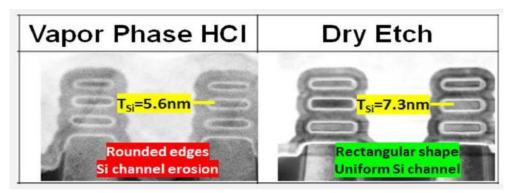
Nano Sheet process challenges:

- Uniformity in rectangle shape
- Mitigation of roughness/residue on patterned surface



TEL's initiative: Gas chemical etch

- High etch selectivity
- High uniformity
- Residue removal/decreased roughness



Source: N. Loubet, et al., IBM, TEL Technology Center, America (IEDM2019)

Leveraging the advantages of gas chemical etch to contribute to leading-edge processes



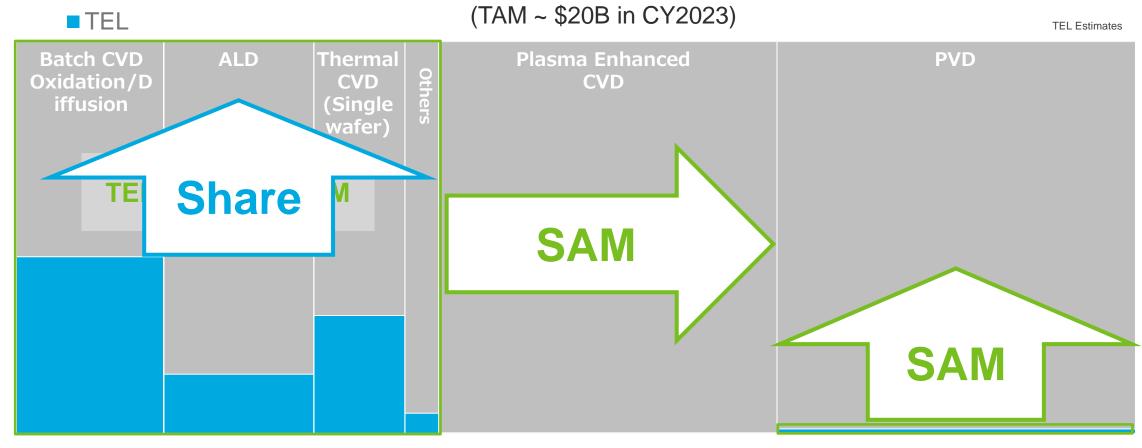
7-2-2. Deposition System



Business Strategy in the Thin Film Deposition Market

Expanding Market Share and SAM*

TEL's Market Share and SAM in Thin Film Deposition



* SAM: Served Available Market



Strategies in the Film Formation Business 1: Expand SAM with Single Wafer CVD

Triase^{+™}



Episode™ 1



Episode™ 2 DMR*



Episode™ 2 QMR**



Single Reactor
Existing Platform

Single ReactorEquipped with up to eight process modules

*Duo Matched Reactor

Achieved high productivity by processing 2 wfs/PM

Released in July 2024

**Quad Matched Reactor

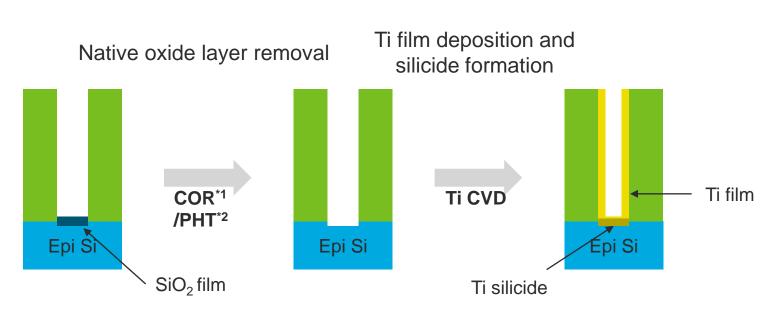
Equipped with a newly developed high-density plasma source

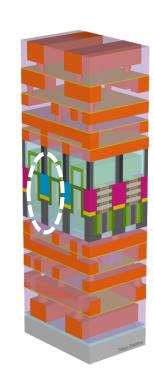
Scheduled for release in 2026



Episode[™] 1: Contact Formation Process

Example of process flow





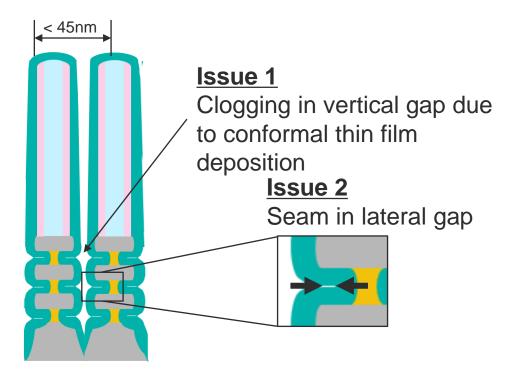
*1 COR: Chemical Oxide Removal

Multiple types of process modules are equipped on a high-vacuum transfer module, and low-resistance contacts are achieved by sequentially processing native oxide layer removal and metal film formation

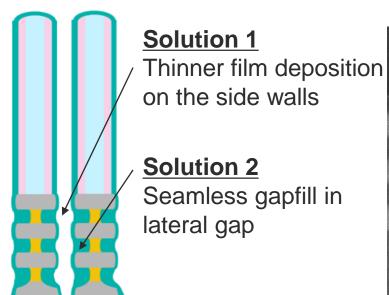
TEL

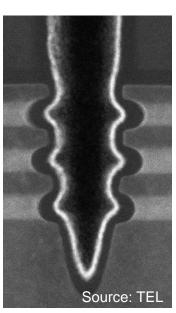
Episode™ 1: Inner Spacer Formation - Lateral Gapfill

Issues:
Leak due to dielectric breakdown due to etching



Solutions : Improve lateral gapfill performance





Realized seamless lateral gapfill using a unique thin film deposition technique and laterally uniform film modification using a newly developed high-density plasma

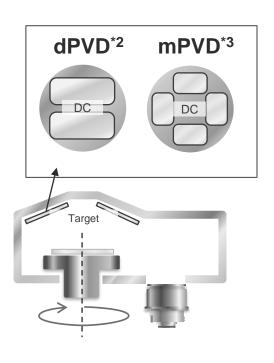
TEL

Strategies in the Film Formation Business 2: SAM Expansion with PVD

LEXIATM -EX Released in December 2024

- Oblique angle sputter with wafer rotation system
 - Excellent thickness uniformity (1σ 0.5%)
- Unique multi-cathode*1 configuration
 - High deposition rate
 - Capability of tuning film composition ratio with multiple materials
- High throughput (~100WPH)
- Significant footprint reduction vs conventional model





Strategies in the Film Formation: Growth in Batch Thermal Process/Deposition

Major applications

- Silicon process in general (dummy gate, channel Si, etc.)
- Batch ALD high-k (capacitor dielectric)
- Plasma/Thermal ALD-SiN/SiO₂
- Batch molybdenum (word line)

Development plans

- Increase load port size (8 lots, 200 wafers/batch)
- Improve exhaust conductance to mitigate pattern loading effect
- Enhance energy efficiency (elevate heater performance)
- Enhance labor reduction (one-touch start-up, self-maintenance, DX)

TELINDY™ PE-II



7-2-3. Cleaning System

Single Wafer Cleaning Strategy

Single wafer cleaning

- Bevel wet etch
 - Expect annual market growth rate of around 10%
 - Contribute to improving customers' yields.
 Maintain a high market share by differentiating through performance in precisely removing film from the outer part of the wafer
- Prevent pattern collapse
 Expand market share by TEL original technology to reduce collapse of high aspect ratio pattern
- Metal etch

Launched new dedicated SPM chambers for controlling selectivity for metal in order to solve reduced yield issues caused by dry etch damage and residue

Without bevel wet etch

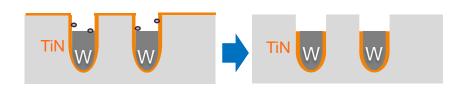
Conventional drying technology

Pattern collapses occur

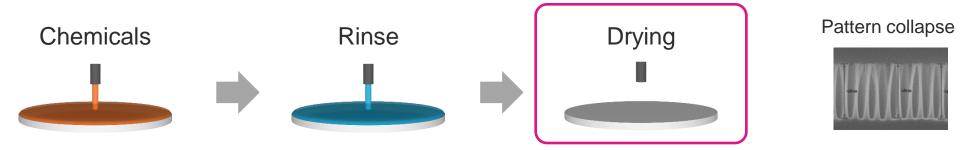
New drying technology

No collapse

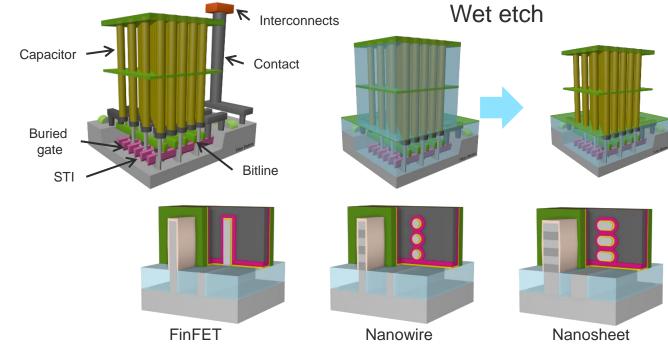
Metal etch process



Technology Challenges in Cleaning for State-of-the-Art Devices



- DRAM
 - Post-STI etch cleaning
 - Mold wet etch after capacitor electrode formation
- Logic
 - Post-fin etch cleaning
 - Post-nanowire/nanosheet formation cleaning

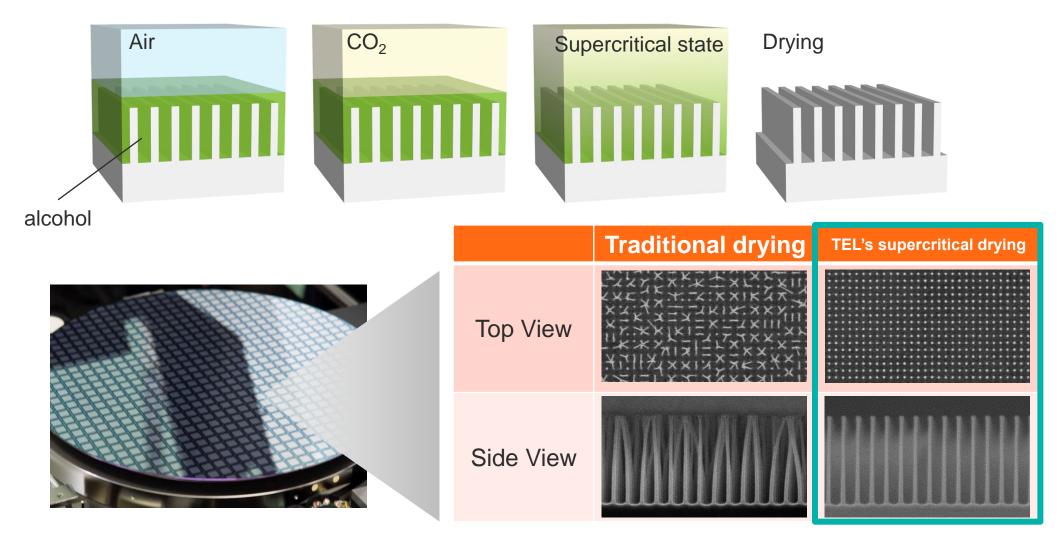


Drying technology more difficult due to further scaling and higher aspect ratios

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in device manufacturing

Supercritical Drying Technology



Supercritical drying technology prevents pattern collapse

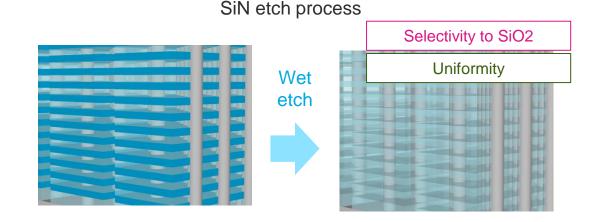
Batch and Scrubber Cleaning Strategy

Batch cleaning

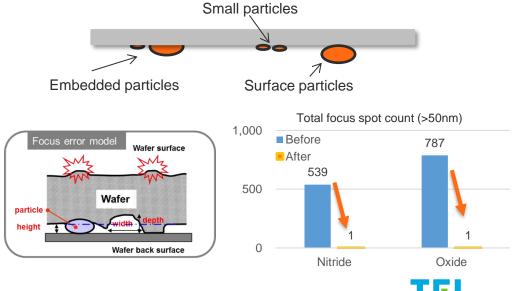
SiN etch and W etch processes for 3D NAND
 Focus on processes that require long durations and advanced process technology. Differentiate by realizing high uniformity, high selectivity and high productivity in wet etch

Scrubber cleaning

Pre-lithography process
 Provide high-value solutions such as reducing particles brought in by wafers, contributing to the improvement of exposure tool availability which have grown increasingly important due to the introduction of EUV



Wafer back and defocus diagram



TEL

ZEXSTATM



A combination of wet bench + single-wafer process

| Method | Features | | |
|-----------------|--|--|--|
| Wet Bench | High-temp/ long-duration process, wet etch | | |
| Single Wafer | Advanced drying technology, particle control | | |

- Target Application
 - Advanced wet etch + advanced dry tech



- Highly selective wet etch process will be required for also 3D DRAM in addition to 3D NAND
- High throughput + surface cleanliness



 High surface cleanliness is required for logic and DRAM

TEL will contribute to customer technology development by continuing to create new value, overcoming the constraints of traditional equipment classifications

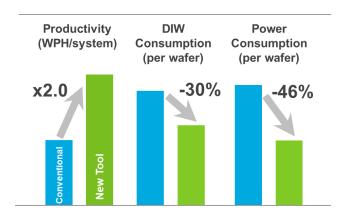
TEL

Development of Cleaning Systems

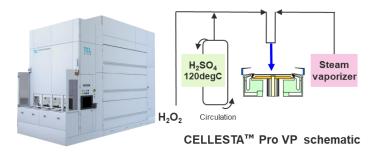
High Productivity Wet Bench (EXPEDIUS™-R)



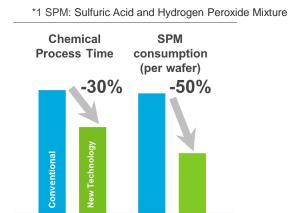
Industry's first large-batch process (increased wafer counts)



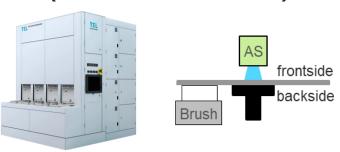
SPM*1 Vapor Technology (CELLESTA™ Pro VP)



Enabled higher temperature process due to a more effective rection by adding water vapor to chemicals

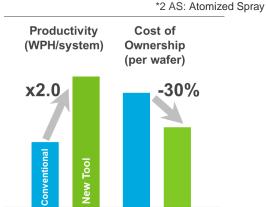


Simultaneous Scrubber (CELLESTA™ MS2)



A tool enabling AS*2 process on wafer frontside and physical brushing process on wafer backside simultaneously in a single chamber

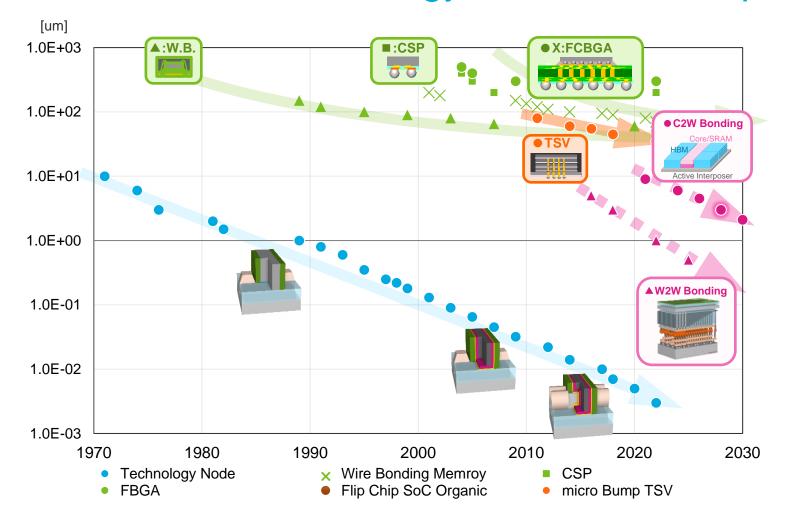
*2 AS: Atomized Spray

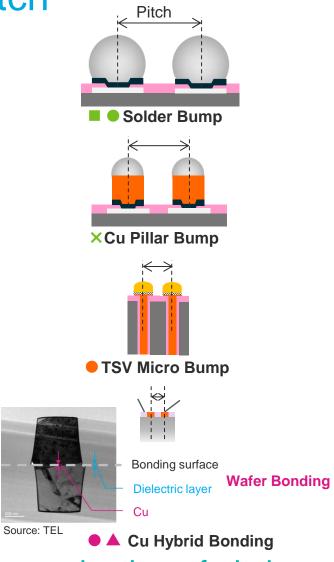




7-3. Backend Business Strategy

Semiconductor Technology Node and Bump Pitch

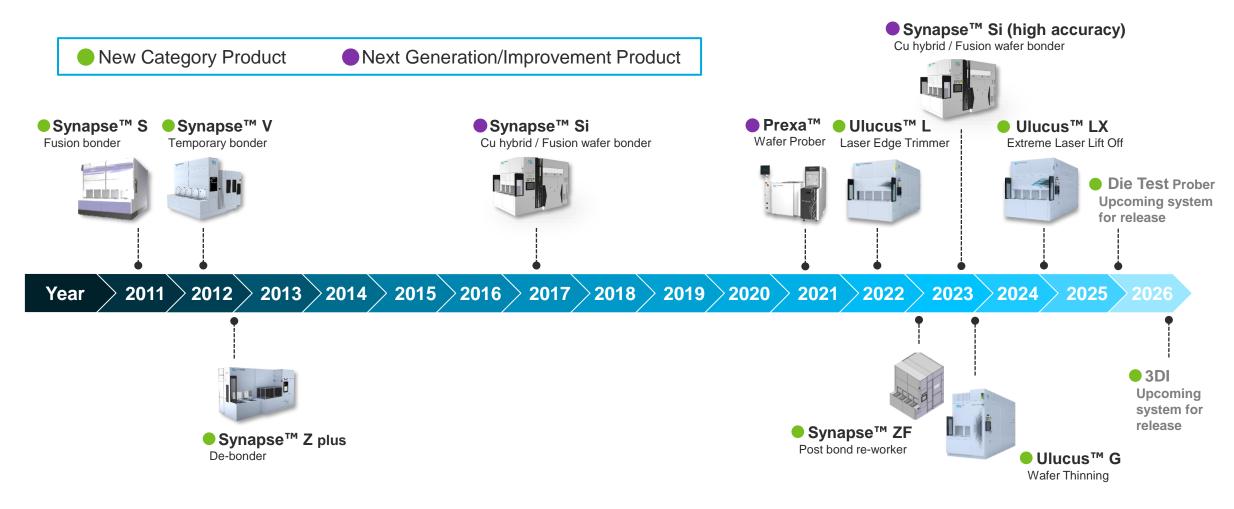




Introduction of wafer bonding technology accelerates further reduction of pitch

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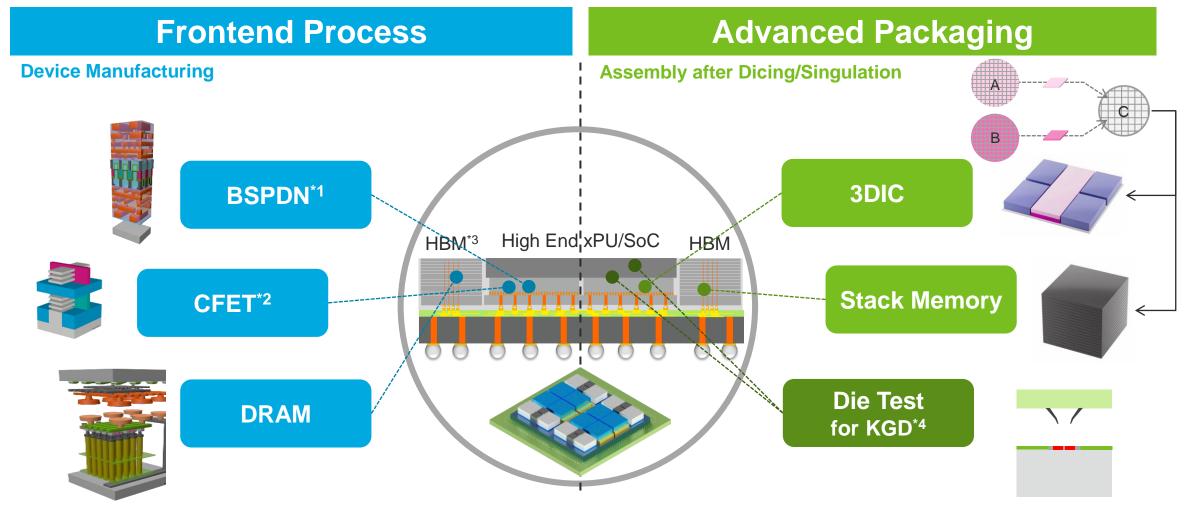
History of Product Launches in Assembly and Test* Systems



Accelerating product development to prepare for the era of 3D integration

TEL

3DI / Test Business Expands Opportunities for HPC/AI Device



^{*1} BSPDN: Back Side Power Delivery Network

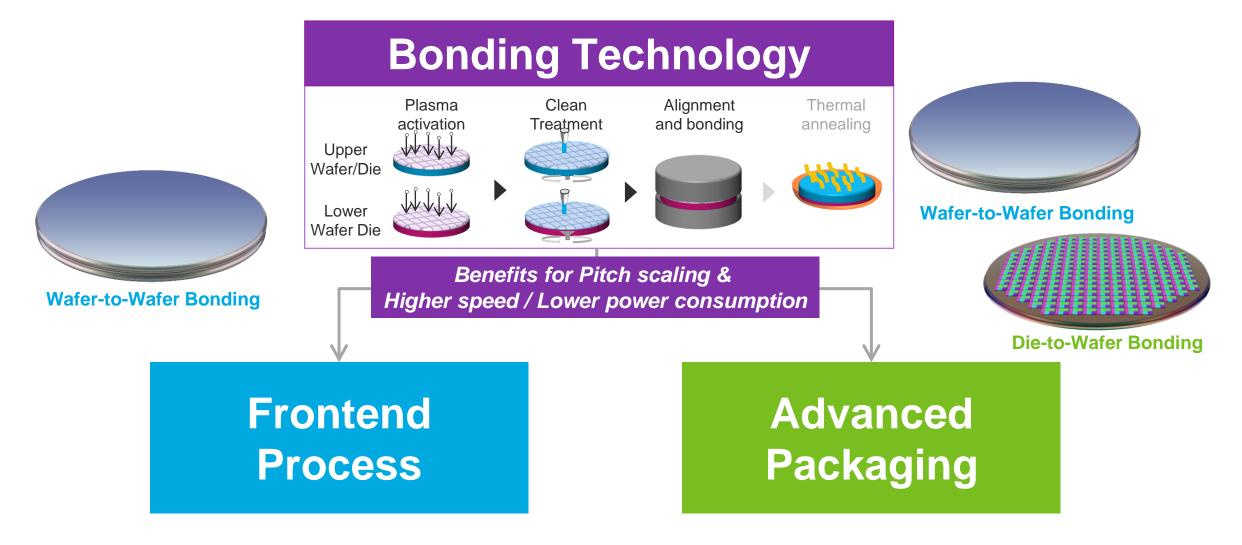


^{*2} CFET: Complementary Field Effect Transistor

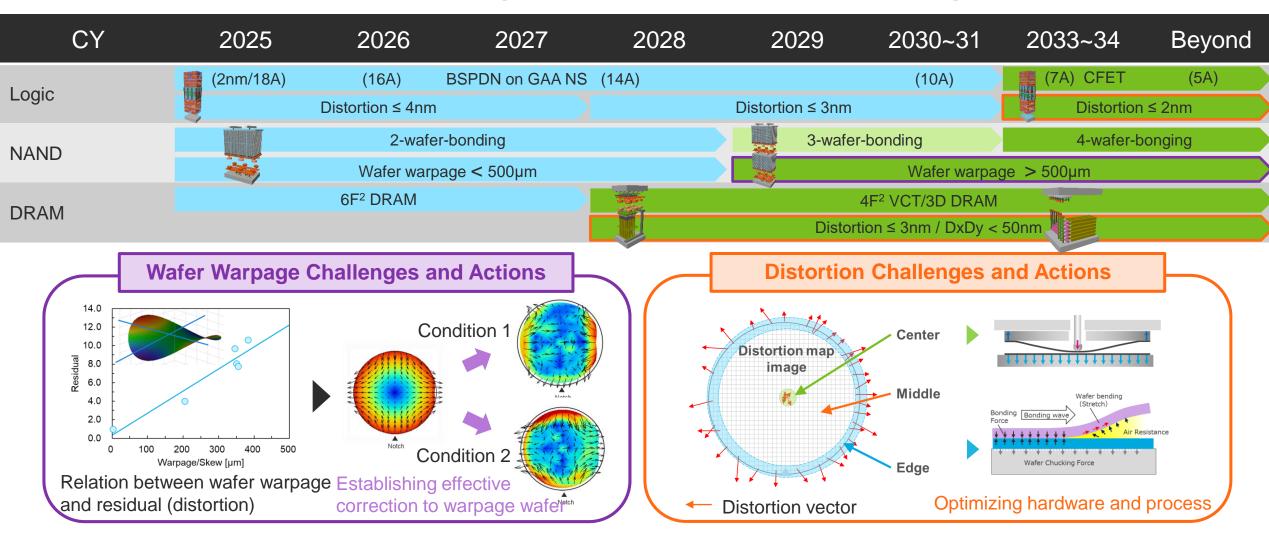
^{*3} HBM: High Bandwidth Memory

^{*4} KGD: Known Good Die

TEL's Opportunities for Bonding Technology

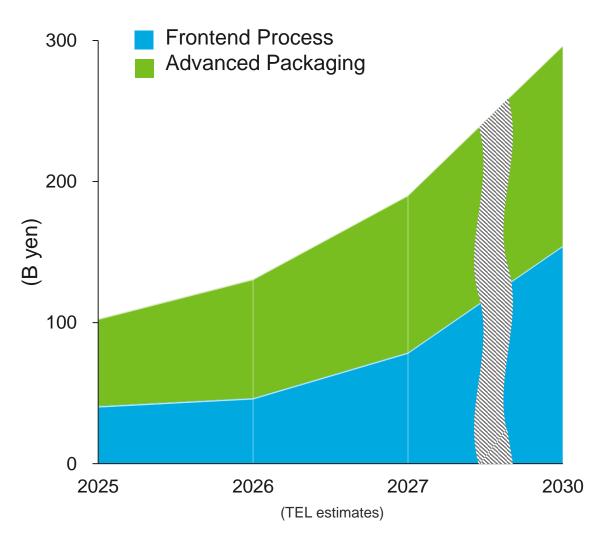


Wafer Bonder Technology Roadmap and Challenges



TEL is developing various technologies in advance to prepare for next-generation devices

Bonding Process Equipment TAM*



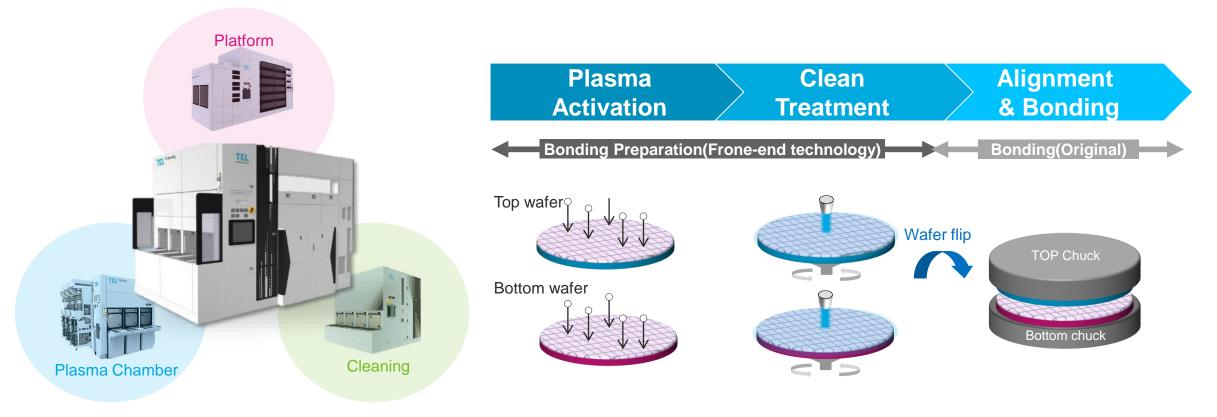
Anticipating a TAM CAGR of 24% from CY2025 to CY2030

- Projected to achieve 300 billion yen by CY2030
- Encompassing both frontend processes and advanced packaging equipment
- Addressing bonding/debonding, slicing, and thinning process equipment utilizing various technologies

* TAM: Total Available Market



Wafer-to-Wafer Permanent Bonder Synapse™ Si



- TEL's existing broad technology and business contributing effective product development/CIPs
- Making good progress with major memory, logic customers towards high volume manufacturing
- Leading W2W Fusion/Cu hybrid bonding technology for next generation device manufacturing

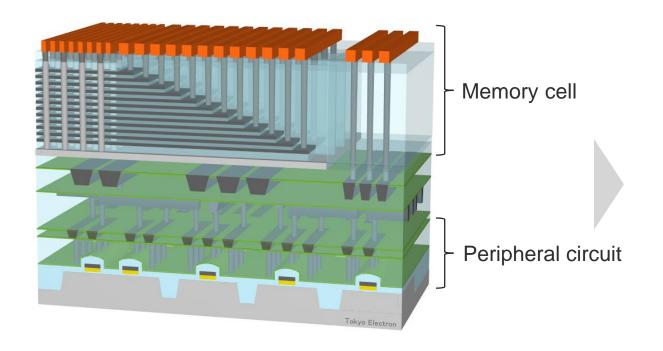
Broad Applications and Expansion of Bonding Technology

| Application | Frontend Process | | | | |
|--------------------|--|--------------------------------------|--|--|--|
| Application | CIS*1 | NAND | DRAM | Logic | |
| Stacking Device | Pixel + (Peripheral) + Logic | 3D NAND : + Cell + Cell + Peripheral | VCT*5 DRAM (Si Substrate) + Peripheral + Cell (Si Substrate) + Cell (Si Substrate) (Si Substrate) + Cell + Cell (Si Substrate) | BSPDN BSPDN & CFET Logic + Logic + Si Substrate + Si Substrate | |
| Bonding | Wafer to Wafer (CHB ^{*3} /Fusion) | Wafer to Wafer (CHB) | Wafer to Wafer Wafer to Wafer (CHB/Fusion) | Wafer to Wafer (HB*6/Fusion) | |
| Structure | The same of the sa | | | | |
| Status | HVM*4 | R&D~HVM R&D | R&D R&D | R&D~HVM R&D | |

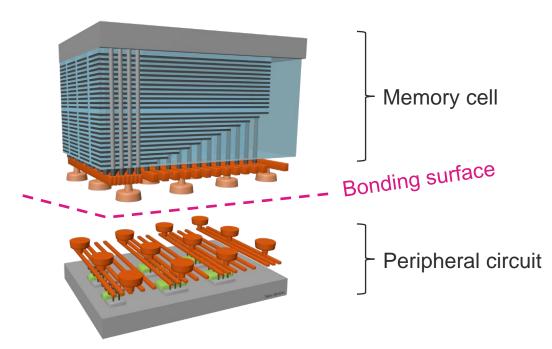
The design of future devices is transitioning from single bonding to multi-bonding structures

Wafer Bonding Application for 3D NAND

Current structure



New structure

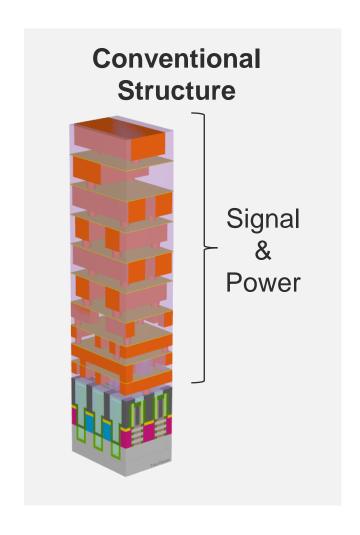


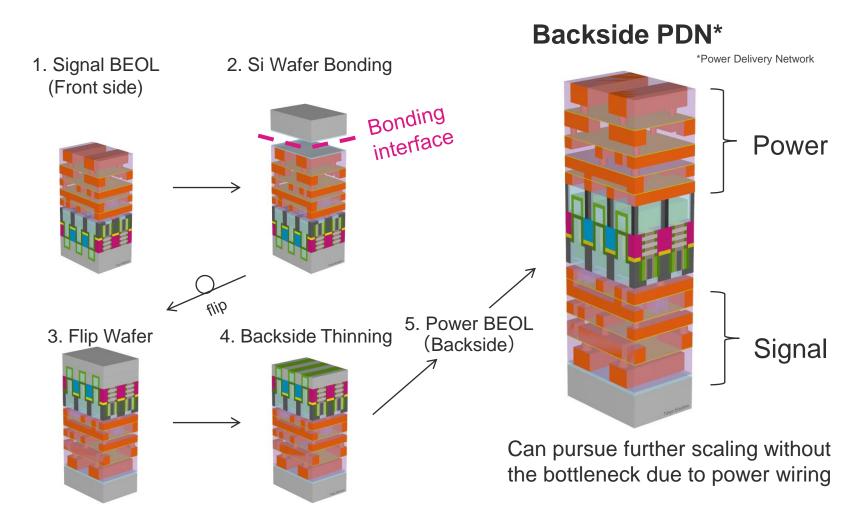
- Peripheral circuit performance deteriorates due to exposure to high temperature during memory cell manufacturing
- ✓ Long interconnects wiring

- ✓ Peripheral circuit is manufactured on the separate wafer and bond to the memory cell wafer
 - higher peripheral circuit performance
 - shorter TAT* process
- Shorter interconnects wiring

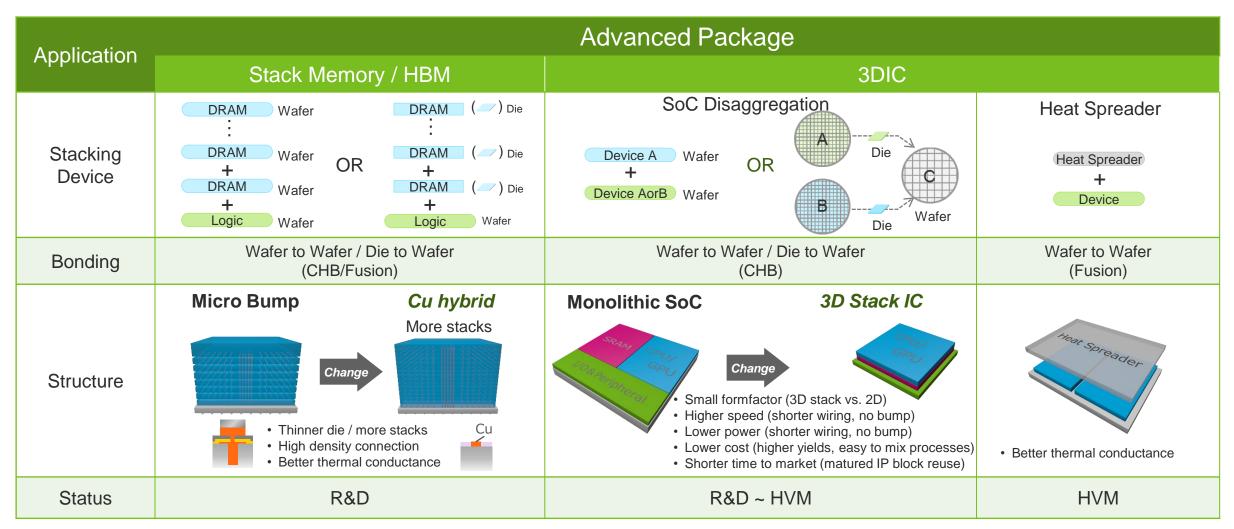
TEL

Wafer Bonding Application for Logic Backside PDN



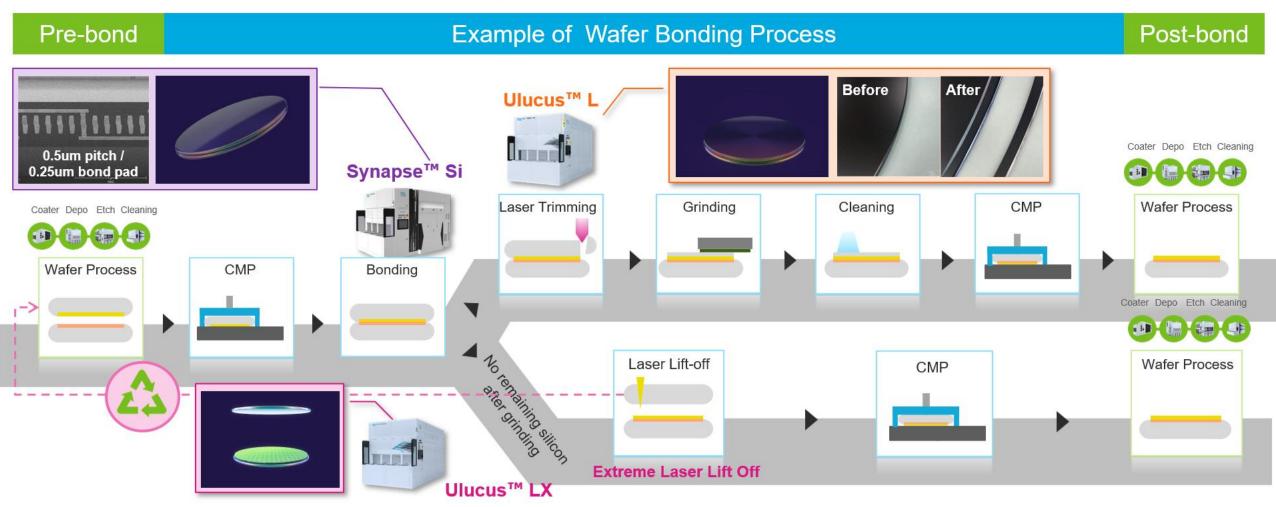


Broad Applications and Expansion of Bonding Technology



The opportunity for CHB/fusion bonding is growing to encompass advanced packaging

Frontend Wafer Bonding Process and TEL Products



Integrating various TEL equipment enables next generation wafer bonding processes that deliver high performance and process efficiency

Laser Trimming System: Ulucus™ L

Concept

- Edge trimming on bonded wafer
- Latest platform utilizing super clean technology from the front-end process, with the integration of laser control technology

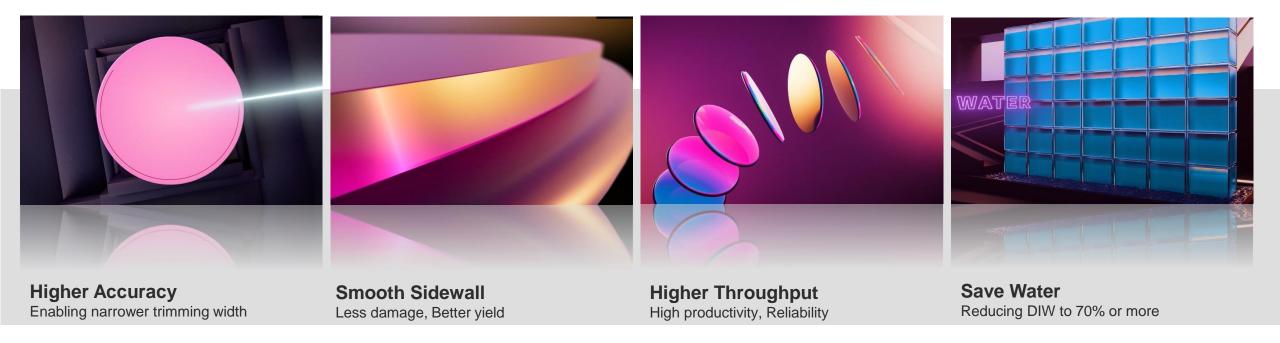


Laser technology realizes high accuracy and quality trimming processes, and environment-friendly capability through the reduction of DIW usage

Laser Trimming System

Revolutionize wafer bonding process with laser technology

Enhance yield and significantly reduce the use of DIW in the edge trimming process



Introducing Ulucus™ LX for Post-Wafer Bonding Process

Si wafer B

Extreme laser lift-off (XLO) technology

- Advanced thinning and critical technology for post-wafer bonding process
- Unique laser technology enables separation of the Si-substrate from the device layer

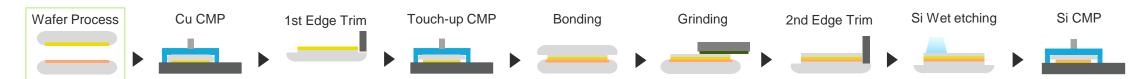


- Enhanced efficiency in silicon active areas
- Fewer process steps required
- Reduced need for DI water usage and CO₂ emission
- Opportunity for wafer reuse
- Equipment released in December 2024

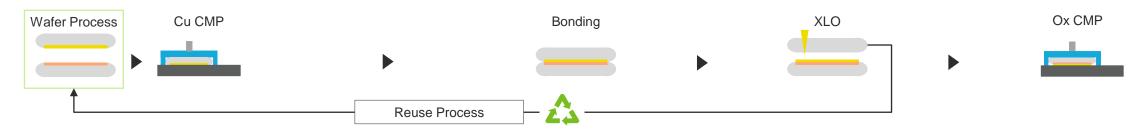


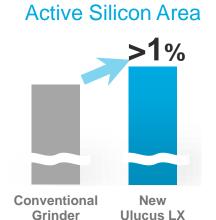
Ulucus™ LX Advantages

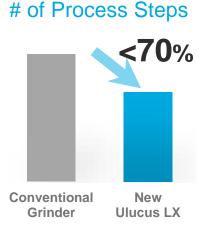
Permanent Bonding Process with Grinding & Blade Edge Trimming (Conventional)

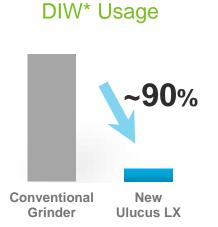


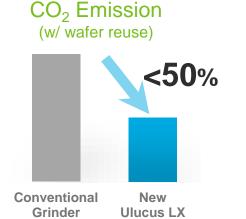
Permanent Bonding Process with XLO (Extreme Laser Lift Off)











→ Advantage Over Grinder

No Silicon Sludge

Source: TEL

8. MAGIC Market and Field Solutions Business Initiatives

MAGIC market

- Expected market growth of 2x
 (approximately \$25B in 2023, projected \$50B in 2030)
- Developing and supplying equipment for MAGIC
- Demo line ready for 200mm MAGIC
 - Yamanashi, Kumamoto, Miyagi
 - Massachusetts, Minnesota, Florida







Equipment for Mature Generations

- Reengineered equipment for 200mm wafer
 - Thermal deposition systems, coater/developer, etch systems, etc.

 Sales expansions not only for replacement demand of existing customers, for emerging customers and for emerging applications

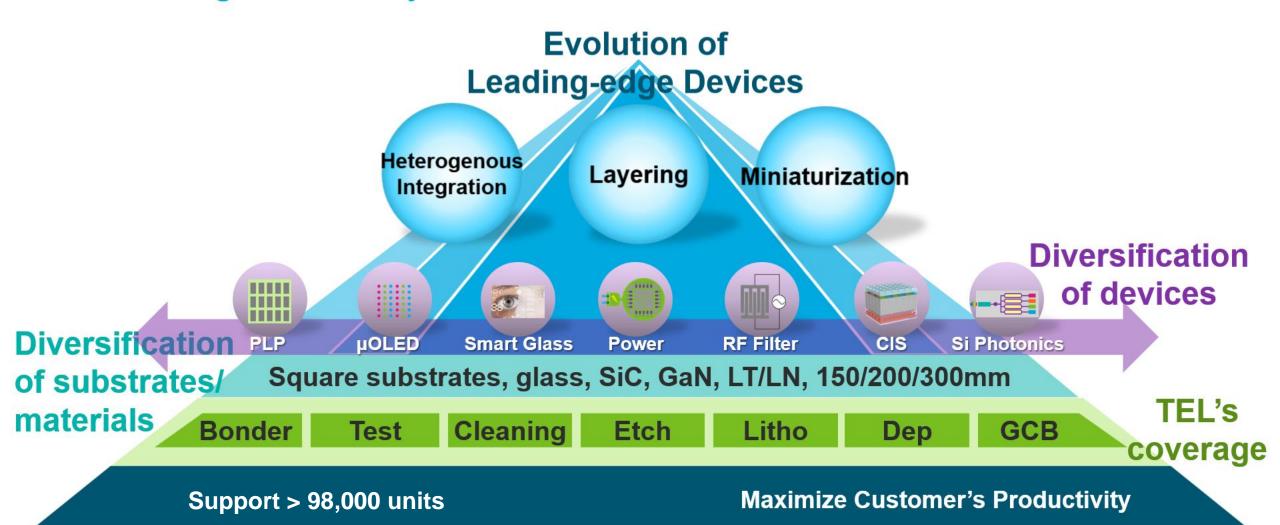
- Equipment for power devices
 - Equipment for SiC wafer, 300mm etch system
 - Respond to the demand for power devices, such as for representative automotive, expanding usage across various fields.



SiC epitaxial CVD system

By integrating our technological assets with new technologies, improve productivity and reduce impact on the environment

Providing Diverse Systems and Solutions for Diverse Needs



Field Solutions

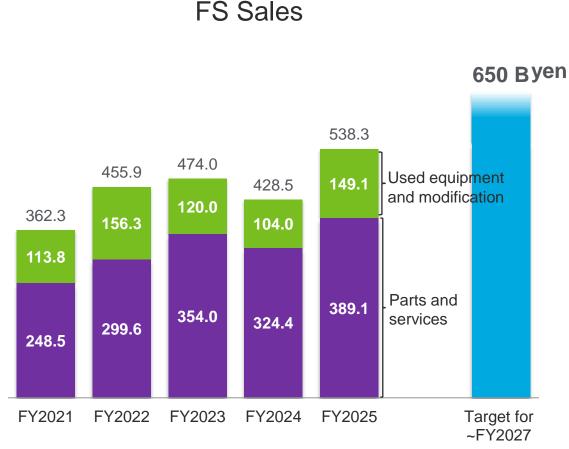


Basic Strategy for Field Solutions (FS)

- Deploying solution business based on installed base
- Development and promotion of advanced Field Solutions
 - Providing leading-edge and sustainable support that utilizes the latest technology, such as DX
 - Development of remote maintenance support and training tools
- Enhancing the front-lines engineers and capabilities
 - Continuous skill improvement for field engineers

Support customers to maximize their business operations through services with high added value

Field Solutions (FS) Sales Results and Business Contents



Parts and repair

- Predictive maintenance for parts deterioration
- Appropriate parts inventory management and prompt delivery

Services

- Providing "comprehensive contract type" services that encompass everything from equipment delivery to after-care maintenance
- Proposing solutions that address customer demands and maximizing equipment utilization rates

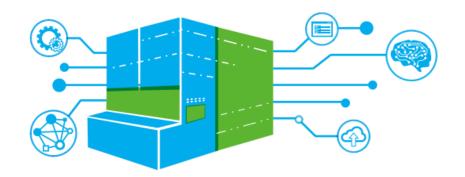
Modification

- Productivity improvement
- Yield improvement

SAM*1 is expanding with 98,000*2 installed base currently and increasing by approx. 4,000 to 6,000 units each year

Advanced Field Solutions

TELeMetrics™



- Monitoring data on individual equipment
- Knowledge management and accumulation of problem case studies

Remote Support

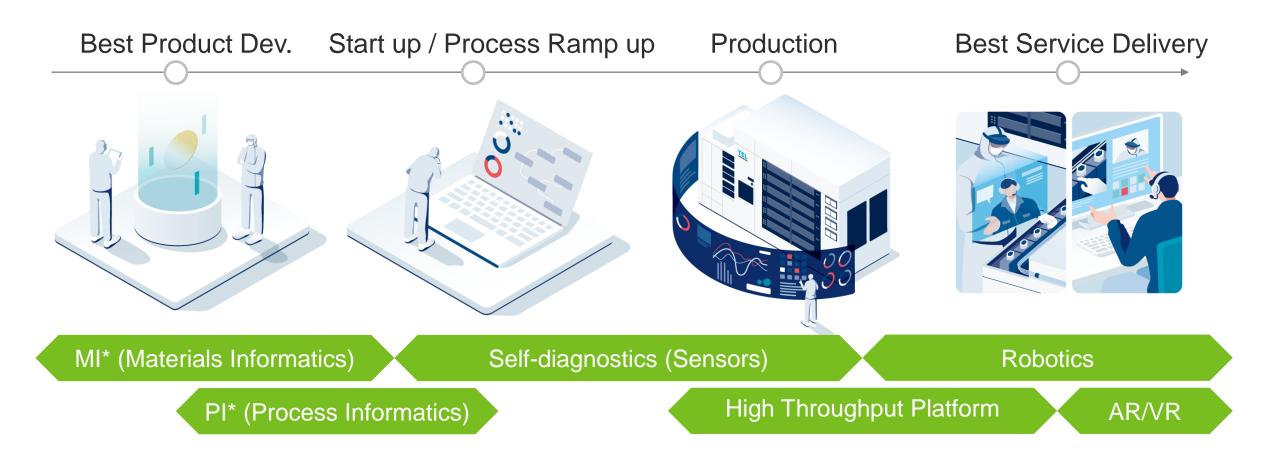


- Minimization of downtime through predictive maintenance of equipment
- Remote support that enables prompt response even under travel restrictions

Proposing solutions with high added value centered around "TELeMetrics™" that utilize DX

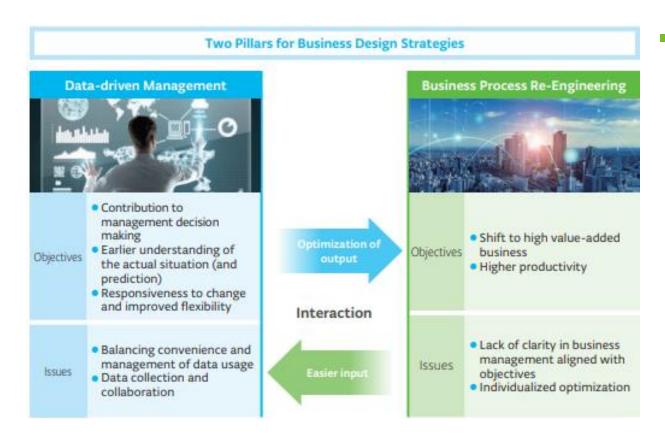
9. Digital Transformation (DX) Initiatives

Leveraging DX in each step of Product Lifecycle



Developing digital enablers for use throughout Product Lifecycle (PLC) to leverage productivity and profitability

Leveraging DX in Business Operations



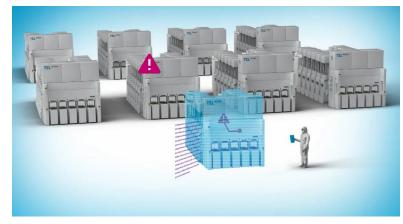
- Business Process Design Strategy Division
- Promote DX through the reciprocity
 between data-driven management and
 business process re-engineering.
- Create environments that utilize digital technologies such as generative AI.
- Cultivate a DX culture through change management and promote sustainable growth.

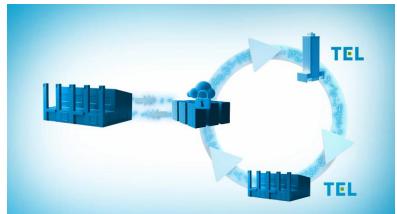
Example Activity 1: Digital Technologies to Increase Customer Value in Etch Equipment







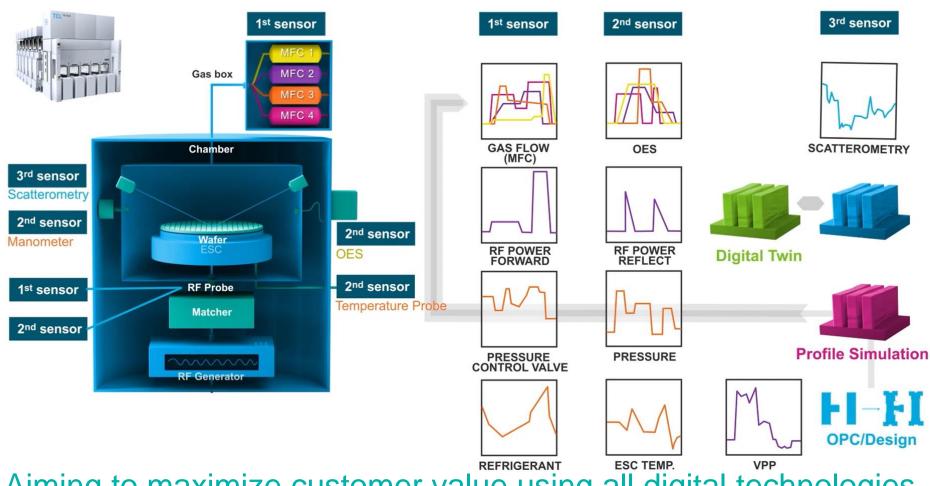






Aiming to maximize customer value using all digital technologies

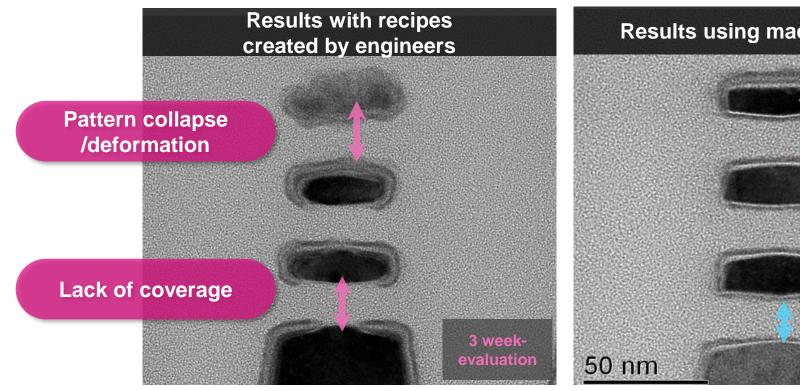
Example Activity 2: Digital Technologies to Increase Customer Value in Etch Equipment

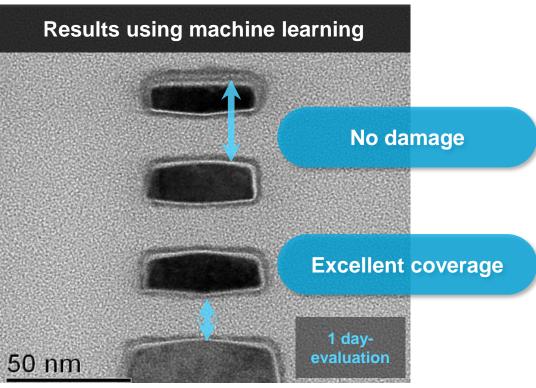


Aiming to maximize customer value using all digital technologies

Example Activity 3: Increasing Productivity of R&D

Process Informatics





Source: Tokyo Electron Technology Solutions Limited / Tokyo Electron Limited

Achieved good step coverage with no pattern deformation in the ALD process by machine learning

Example Activity 4: Increasing Productivity of Equipment

Improving Utilization of Etch Equipment

via sensors



Seasoning at the right time with endpoint detection

*ISSM 2020, from "Seasoning Optimization by using Optical Emission Spectroscopy," published by the Company

Feedback from the sensor provided an appropriate understanding of chamber conditions and improved utilization of equipment

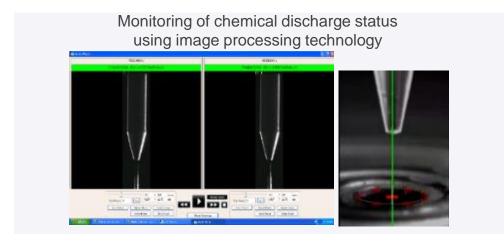
4. Model learning and

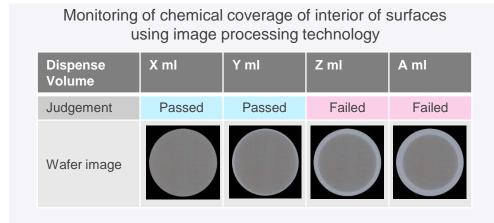
evolution

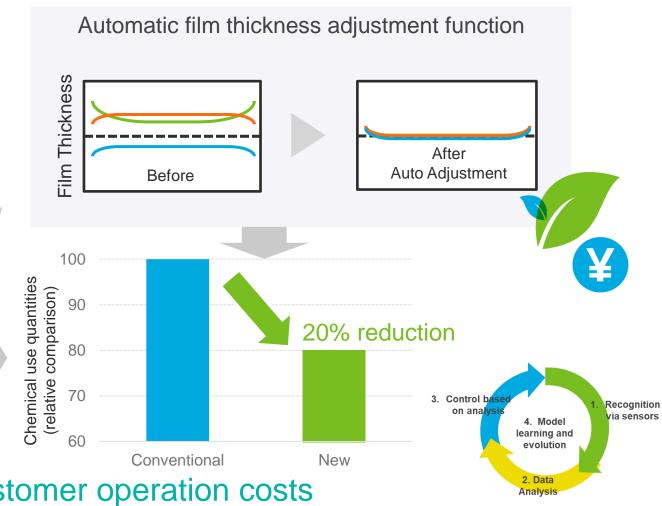
2. Data
Analysis

Example Activity 5: Increasing Operation Cost of Equipment

Reducing Chemicals of Coater/Developer

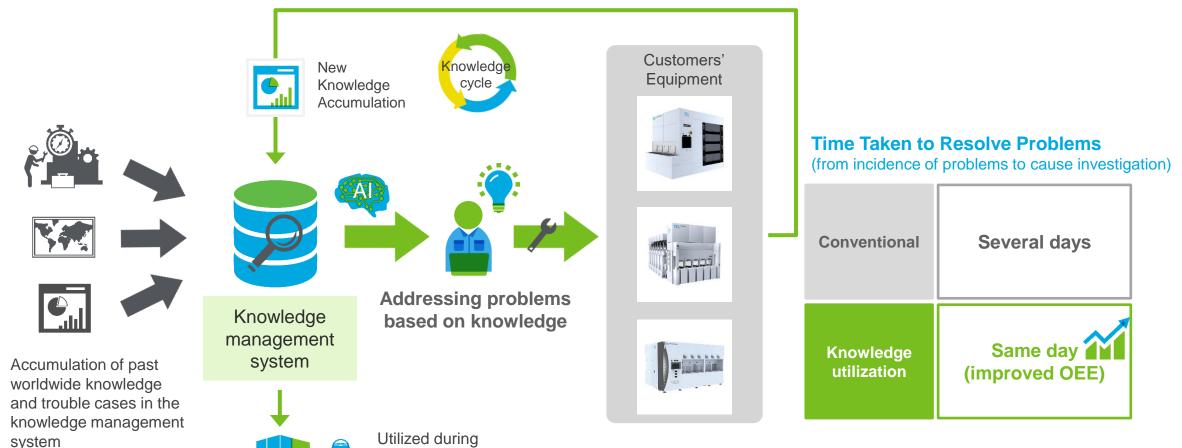






Contributed to customer operation costs and the environment by using machine learning

Example Activity 6: Improving Overall Equipment Effectiveness



OEE: Overall Equipment Effectiveness FMEA: Failure Mode and Effects Analysis

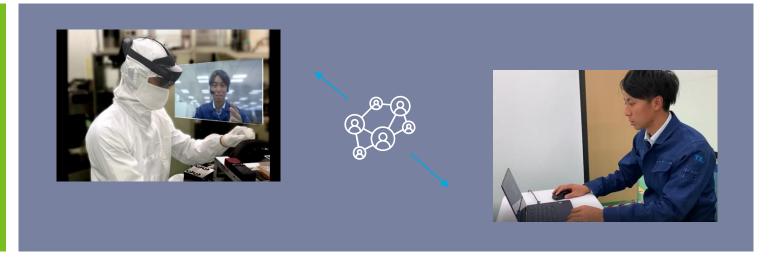
Using the Knowledge Management System to reduce the time taken to resolve problems and improve equipment operation rates

development of

FMEA as well

Example Activity 7: Leveraging DX in Field Solutions

Maximize work efficiency for startup and maintenance in the Clean Room by using smart glasses and remote expert support. Use of AR/VR and DX including digital twin technology.





Use of robots for parts replacement without human assistance is expected to minimize downtime and improve the quality of engineering work.

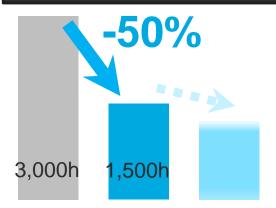
10. Procurement and Manufacturing Strategy

Continuous Production Innovation in Pursuit of Safety, High Quality and High Reliability

- Build a production system able to quickly respond to market changes
- Shorten time from new product development to mass production
- Shorten production lead times: Achieve 100% module shipment
- Utilize DX and automation in manufacturing, and expand automated warehouse
- Significantly reduce equipment start-up time (One-touch start-up)
 - Reduce start-up time up to 75% (primary target), One-touch (final target)



Shorten start-up time



Conventional → after production innovation

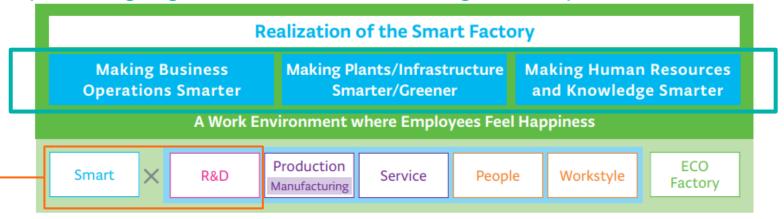
Expected outcome from shorten start-up time

- Enhance productivity and start-up quality
- Reduce accident risks
- Optimize resources and the work-life balance



An Initiative to Promote Shift Left: Smart Factory Concepts

Three elements that are increasingly crucial when providing high value-added technologies and products to customers



Various measures in place for the realization of Smart R&D

Example ①

Analyzing and utilizing internal data collected through DX creates an environment where inexperienced engineers can learn from the knowledge and experience of expert engineers at any time

Shorten the development period by providing timely feedback on the development of new products

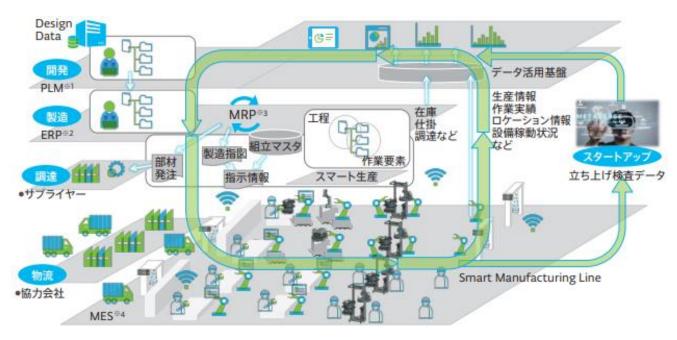
Example 2

Automating operations that engineers had repeatedly performed using digital technology

Enabling employees to focus on work with high added value

Innovative Production Capabilities by DX: Smart Manufacturing

Striving to build superior production capabilities that enable optimal decision-making and immediate action through the cooperation and digitization of all production-related data in real time



- *1 PLM: Product Lifecycle Management
- **2 ERP: Enterprise Resource Planning
- **3 MRP: Material Resource Planning
- **4 MES: Manufacturing Execution System
- **5 BOM: Bill of Material

- Improve core system
 - Production leveling
 - Increase MPR processing capability for procurement
- Introduce PLM-DX and BOM^{※5} concept
 - Enhance production capability
 - Minimize manufacturing lead time
 - Increase design efficiency
 - Reduce new product development period by half

Smart R&D Concept

Leveraging Smart Manufacturing concept to realize efficient and stable cutting-edge manufacturing lines that produces high-quality products__

Build a Sustainable Supply Chain

- Tokyo Electron supports

 SUPPLIANTED

 TOKYO ELECTRON SUPPORTS

 SDGS
- Fair and transparent relationships and reliable trust relationship with our business partners
 - Implement CSR/BCP assessments based on industry codes of conduct
 - Share knowledge in such areas as safety, quality, the environment and compliance

Production trend briefings
twice a year
(procurement amount ratio: 90%)

Partners Day
once a year
procurement amount ratio: 65%

E-COMPASS

Applaud environmental impact reduction activities, adding environmentally related items to assessment studies

- √ Reduce CO₂ emissions and the amount of energy usage
- ✓ Introduce renewable energy
- ✓ Promote resource conservation
- ✓ Promote waste reduction and recycling
- ✓ Promote activities for reducing the environmental impact of logistics





Procurement BCP and Proactive Procurement Activities

Mid- and long-term forecast
Promote "Shift Left" procurement strategy
Build BCP system resilient to
procurement difficulty

Safety stock Inventory liquidity

Oversee whole supply chain from upstream to downstream

Visualize and grasp risks

Visualize supply chain

Supply chain responsive
to any kind of risks
(Raw materials, parts,
processing and assembly)
Strong and reliable supply chain

Risk management on business partners
Strengthen partnership

Measures for procurement BCP

Early procurement of parts

- Early procurement for long term
- Ensure inventory exchange flexibility among factories
- Inventory reductions in total

Secure semiconductor devices

- Secure semiconductor devices for our equipment
- Visualize and streamline distribution channel
- Collaborate with semiconductor makers
- = TEL can be a customer of our customers

Parts and Suppliers

- Identify and analyze risk parts
- Multi sourcing of producing countries
- Standardization, centralization and decentralization of parts
- Measures to secure capacity for us



New Production Building Construction at Tokyo Electron Miyagi

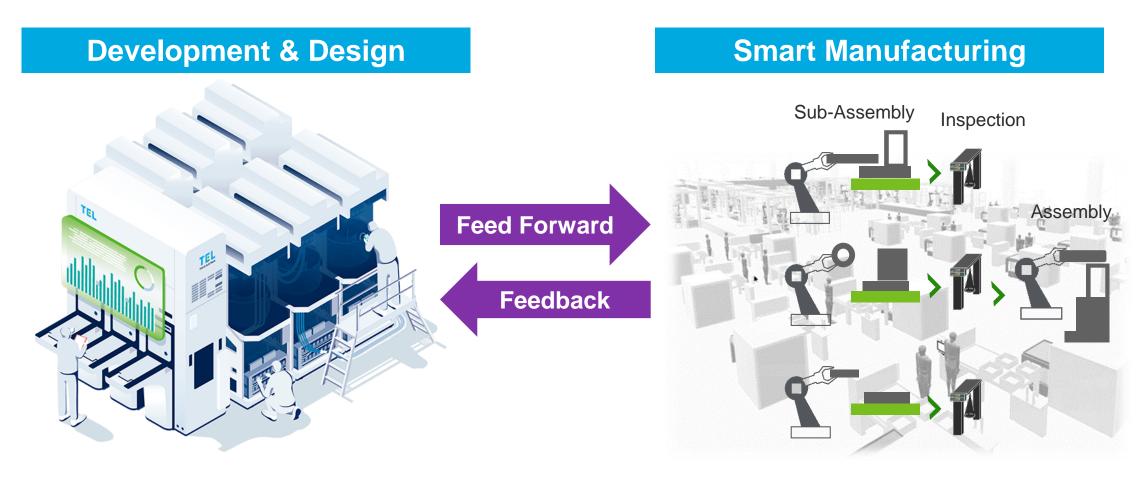
- Total floor area: Approx. 88,600m² (planned; excluding the ancillary facility area)
- Structure: Steel frame structure with a base isolation system
- Number of floors: 5 above ground
- Construction cost: Approx. 104B yen
- Purpose: Manufacture of etch systems

Miyagi innovative Production Center (Completion scheduled for summer 2027)



Realize the Smart Production concept by automating logistics functions and mechanizing manufacturing processes to provide high production capacity/quality/efficiency production lines

Smart Manufacturing to Achieve High Quality and Productivity



By centralizing development and production in TEL Miyagi, we ensure continuous concurrent engineering and advanced manufacturing capabilities

Vision for Smart Production

Achieve sustainable manufacturing for the future

Overwhelming Efficiency

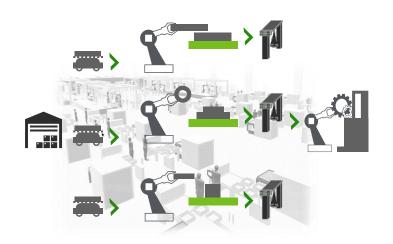
through automation and standardization

Enhancing Adaptability

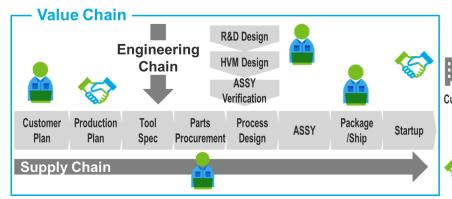
to internal and external environmental changes

Product & Service Quality Improvement

through enhanced value chain

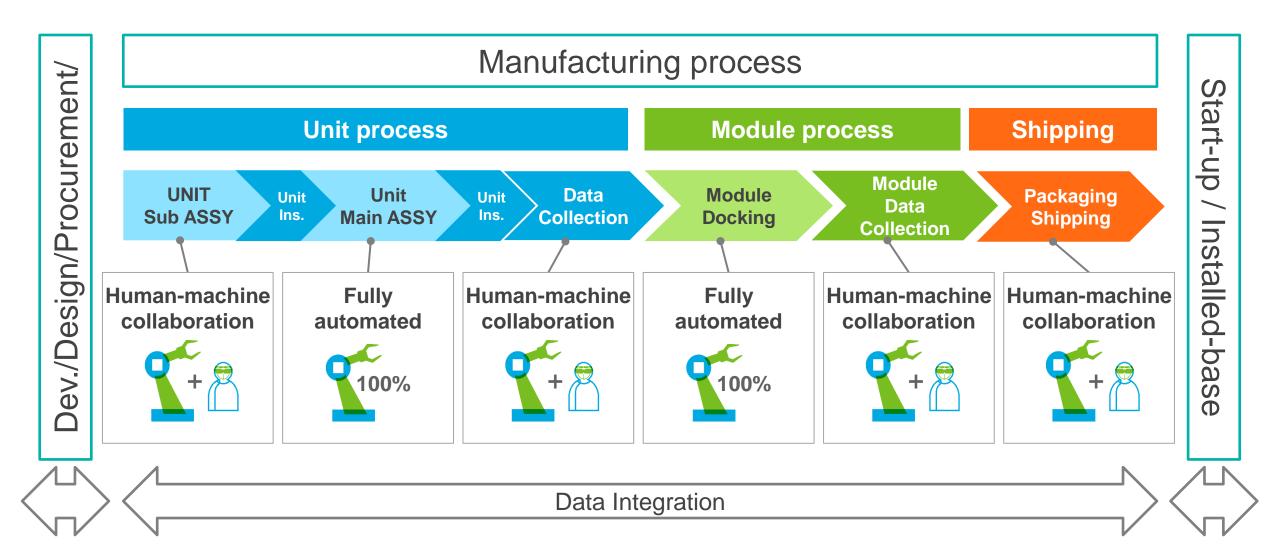








Concept of Smart Production



Appendix: Data Section

Financial Summary

(Billion yen)

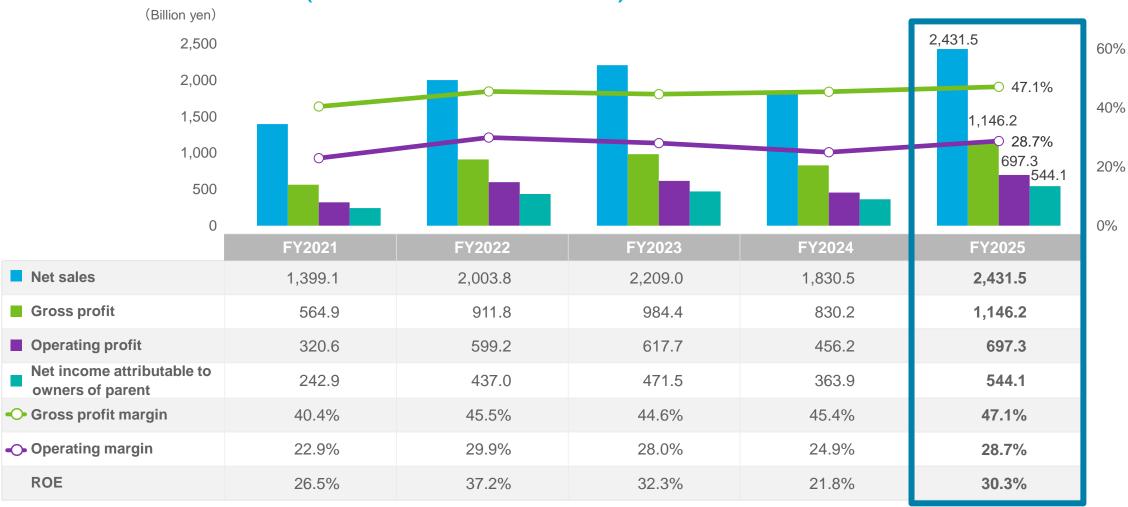
| | FY2024 | FY2025 | FY2025 vs FY2024 | (Reference) FY2025 estimates announced on February 6, 2025 |
|---|----------------|------------------|------------------------|--|
| Net sales | 1,830.5 | 2,431.5 | +32.8% | 2,400.0 |
| Gross profit Gross profit margin | 830.2 45.4% | 1,146.2 47.1% | +38.1% +1.7pts | 1,129.0 47.0% |
| SG&A expenses | 374.0 | 448.9 | +20.0% | 449.0 |
| Operating income Operating margin | 456.2 24.9% | 697.3 28.7% | +52.8% +3.8pts | 680.0 28.3% |
| Income before income taxes | 473.4 | 706.1 | +49.1% | 691.0 |
| Net income attributable to owners of parent | 363.9 | 544.1 | +49.5% | 526.0 |
| EPS (Yen) | 783.75 | 1,182.40 | +50.9% | 1,142.47 |
| R&D expenses | 202.8 | 250.0 | +23.2% | 254.0 |
| Capital expenditures | 121.8 | 162.1 | +33.1% | 170.0 |
| Depreciation and amortization | 52.3 | 62.1 | +18.7% | 63.0 |

^{1.} In principle, export sales of Tokyo Electron's products is denominated in yen. Although some sales and expenses are denominated in foreign currencies, the impact of foreign exchange rate fluctuations on profits is negligible, unless extreme fluctuations occur.



^{2.} Profit ratios are calculated using full amounts, before rounding.

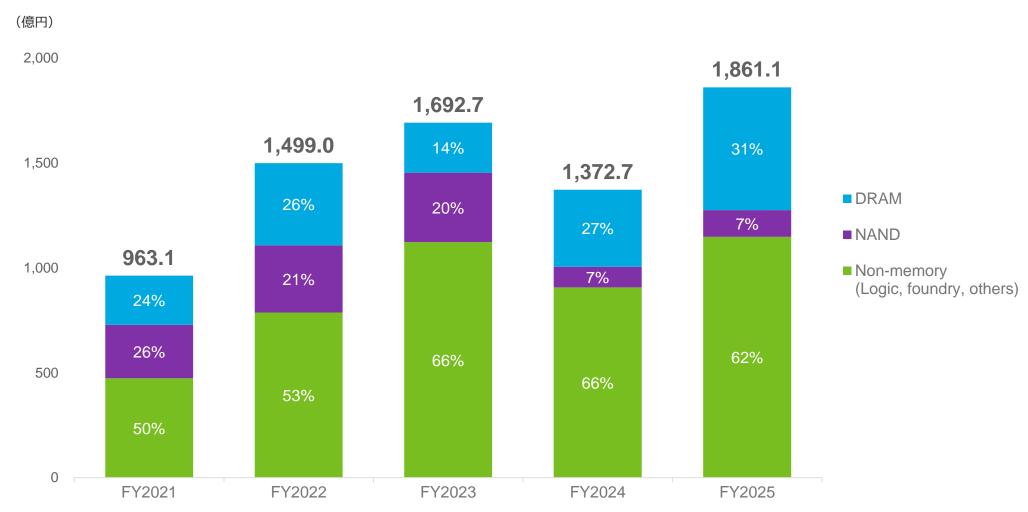
Financial Trend (FY2021~FY2025)



From the beginning of FY2022, the Company applies "Accounting Standard for Revenue Recognition" (ASBJ Statement No. 29).

Net sales, gross profit, operating profit and net income reached record high

SPE New Equipment Sales by Application



^{1.} SPE: Semiconductor Production Equipment



^{2.} Percentages on the graph show the composition ratio of new equipment sales. Field Solutions sales are not included.

SPE New Equipment Sales by Product



Percentages on the graph show the composition ratio of new equipment sales. Field Solutions sales are not included.

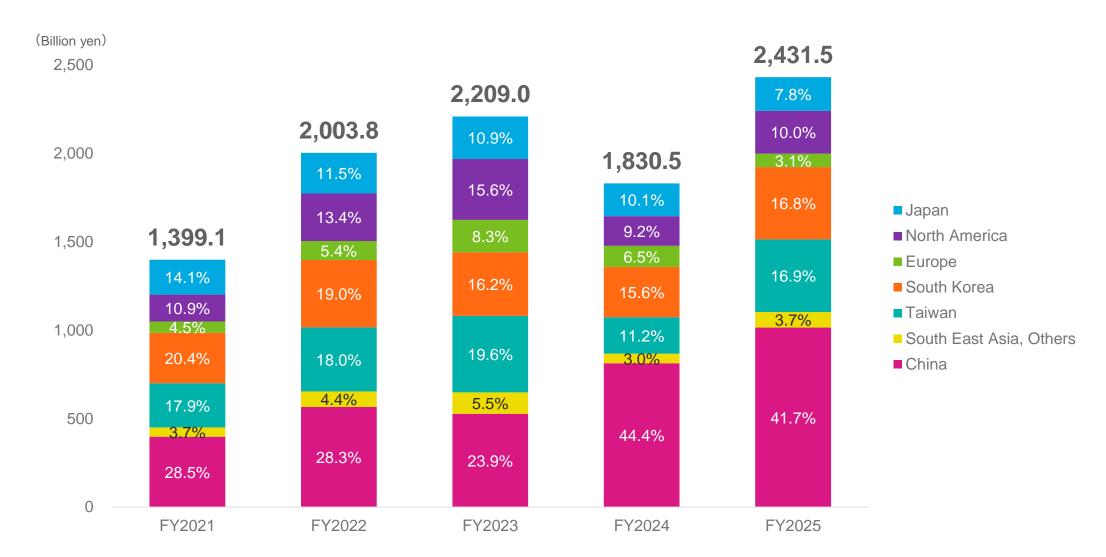


Field Solutions Sales





Sales by Region

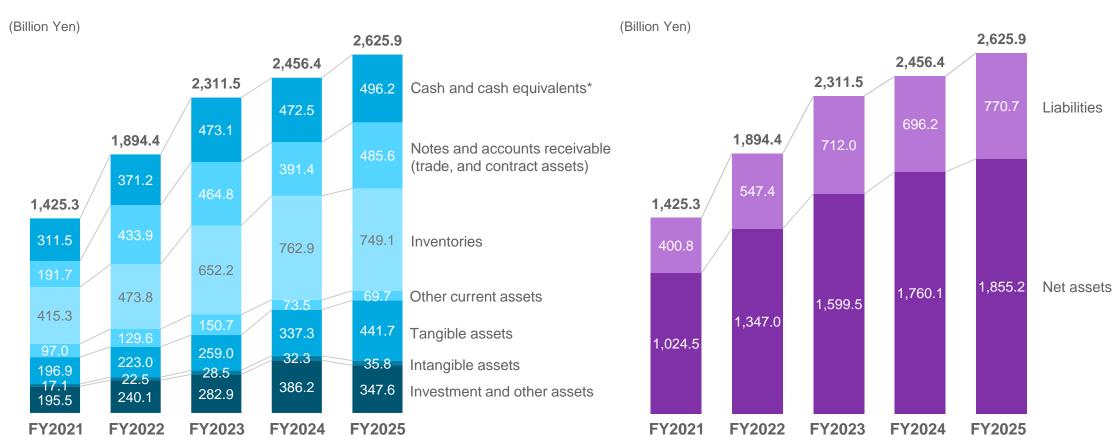




Balance Sheet

Assets

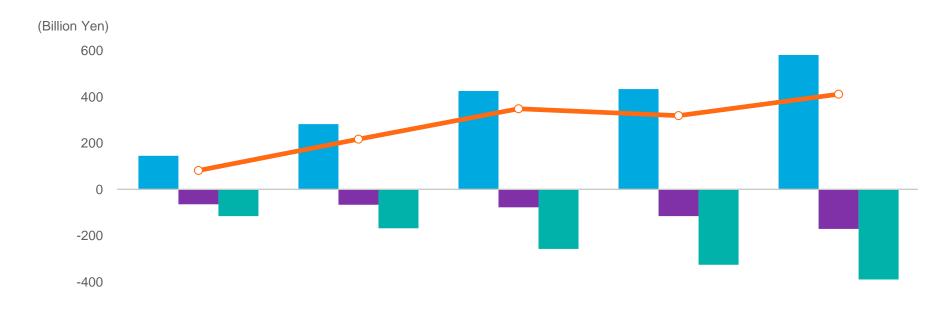
Liabilities and Net Assets



*Cash and cash equivalents: "Cash and deposits" + "Short-term investments", etc. ("Securities" in Balance Sheet).



Cash Flow



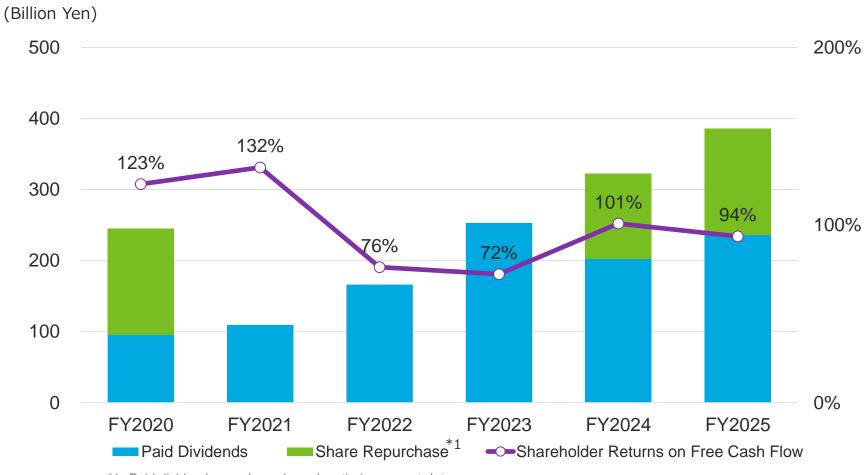
| -600 | | | | | |
|---|--------|--------|--------|--------|--------|
| | FY2021 | FY2022 | FY2023 | FY2024 | FY2025 |
| Cash flow from operating activities | 1,458 | 2,833 | 4,262 | 4,347 | 5,821 |
| ■ Cash flow from investing activities*1 | -632 | -656 | -767 | -1,150 | -1,697 |
| Cash flow from financing activities | -1,145 | -1,672 | -2,565 | -3,250 | -3,888 |
| ◆Free cash flow*² | 826 | 2,177 | 3,494 | 3,196 | 4,124 |
| Cash on hand*3 | 3,115 | 3,712 | 4,731 | 4,725 | 4,962 |

^{*1} Cash flow from investing activities excludes changes in time deposits and short-term investments.

^{*2} Free cash flow = "Cash flow from operating activities" + "Cash flow from investing activities" (excluding changes in "Time deposits" and "Short-term investments").

^{*3} Cash on hand includes "Cash and cash equivalents" + "Time deposits and short-term investments" with original maturities of more than three months.

Shareholder Returns Trend



*1 Paid dividends are shown based on their payment date.

Aim for continuous high level of cash generation and shareholder returns

Financial Summary (Quarterly)

(Billion yen)

| | FY2025 | | | FY2 | 026 | VS. | vs. |
|---|----------------|----------------|----------------|----------------|----------------|-------------------|------------------|
| | Q2 | Q3 | Q4 | Q1 | Q2 | Q1 FY2026 | Q2 FY2025 |
| Net sales | 566.5 | 654.5 | 655.4 | 549.5 | 630.0 | +14.6% | +11.2% |
| Gross profit Gross profit margin | 259.9 45.9% | 311.7 47.6% | 310.5 47.4% | 253.9 46.2% | 284.8 45.2% | +12.2% -1.0pts | +9.6% -0.7pts |
| SG&A expenses | 111.7 | 112.1 | 126.7 | 109.2 | 126.4 | +15.7% | +13.1% |
| Operating income | 148.1 | 199.6 | 183.7 | 144.6 | 158.4 | +9.5% | +6.9% |
| Operating margin | 26.2% | 30.5% | 28.0% | 26.3% | 25.1% | -1.2pts | -1.1pts |
| Income before income taxes | 153.6 | 200.1 | 185.1 | 151.9 | 161.0 | +6.0% | +4.8% |
| Net income attributable to owners of parent | 117.7 | 157.2 | 142.9 | 117.8 | 123.8 | +5.1% | +5.2% |
| R&D expenses | 62.0 | 61.8 | 72.7 | 62.1 | 72.6 | +17.0% | +17.1% |
| Capital expenditures | 53.3 | 50.2 | 34.6 | 52.8 | 91.2 | +72.7% | +71.1% |
| Depreciation and amortization | 14.5 | 16.0 | 18.3 | 17.1 | 19.1 | +11.4% | +31.8% |

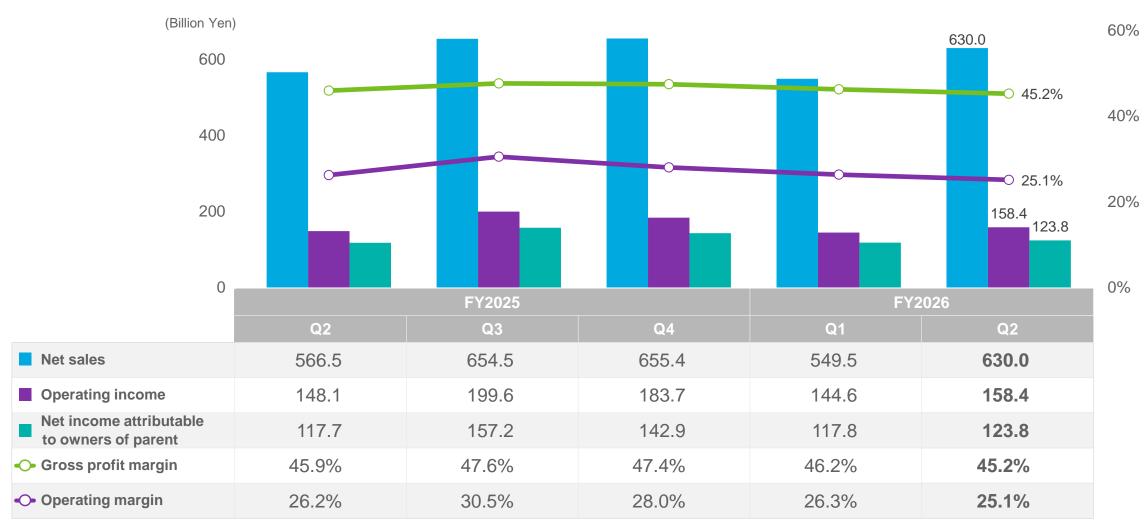
^{1.} In principle, export sales of Tokyo Electron's products is denominated in yen. Although some sales and expenses are denominated in foreign currencies, the impact of foreign exchange rate fluctuations on profits is negligible, unless extreme fluctuations occur.



^{2.} Profit ratios are calculated using full amounts, before rounding.

^{3.} FY202x refers to the financial year ending in March 202x.

Financial Performance (Quarterly)



Financial Summary (Semiannual)

(Billion yen)

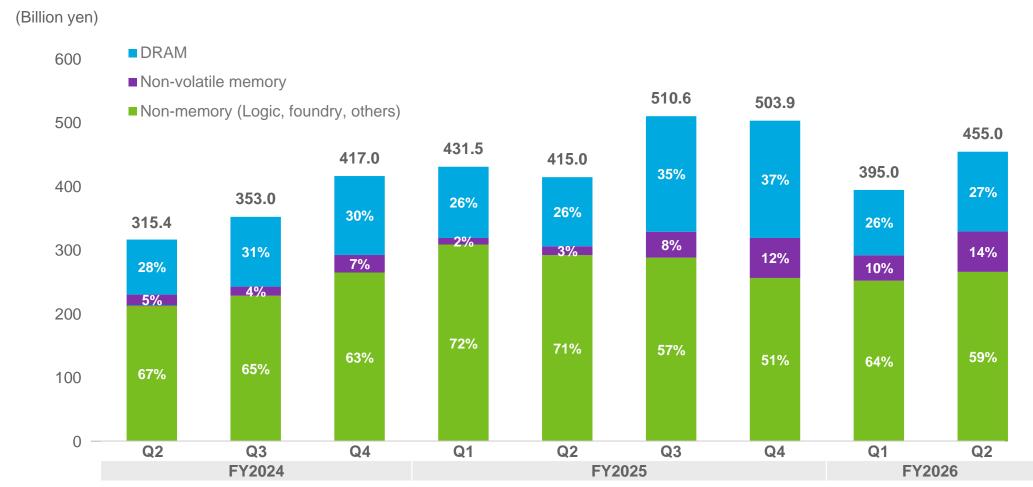
| | FY2 | 025 | FY2026 | VS. | VS. | Reference: H1 FY2026 |
|---|----------------|----------------|----------------|-------------------|------------------|-----------------------------|
| | H1 | H2 | H1 | H2 FY2025 | H1 FY2025 | Estimate (As of July 31) |
| Net sales | 1,121.6 | 1,309.9 | 1,179.6 | -9.9% | +5.2% | 1,150.0 |
| Gross profit Gross profit margin | 523.9 46.7% | 622.3 47.5% | 538.8 45.7% | -13.4% -1.8pts | +2.8% -1.0pts | 527.0 45.8% |
| SG&A expenses | 210.0 | 238.9 | 235.7 | -1.3% | +12.2% | 239.0 |
| Operating income Operating margin | 313.9 28.0% | 383.4 29.3% | 303.1 25.7% | -20.9% -3.6pts | -3.4% -2.3pts | 288.0 25.0% |
| Income before income taxes | 320.8 | 385.2 | 312.9 | -18.8% | -2.5% | 293.0 |
| Net income attributable to owners of parent | 243.9 | 300.2 | 241.6 | -19.5% | -0.9% | 224.0 |
| R&D expenses | 115.4 | 134.5 | 134.8 | +0.2% | +16.7% | 140.0 |
| Capital expenditures | 77.3 | 84.8 | 144.0 | +69.8% | +86.4% | - |
| Depreciation and amortization | 27.7 | 34.4 | 36.2 | +5.3% | +30.9% | - |

^{1.} In principle, export sales of Tokyo Electron's products is denominated in yen. Although some sales and expenses are denominated in foreign currencies, the impact of foreign exchange rate fluctuations on profits is negligible, unless extreme fluctuations occur.

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^{2.} Profit ratios are calculated using full amounts, before rounding.

SPE New Equipment Sales by Application (Quarterly)



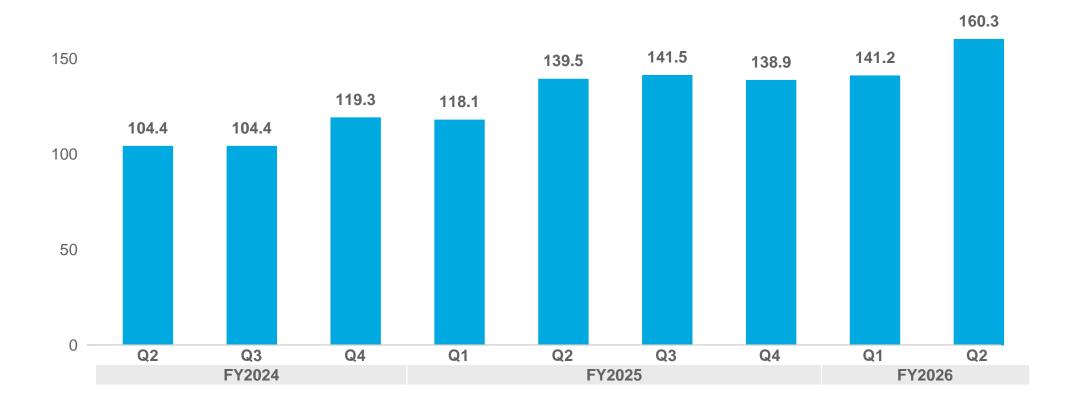
^{1.} SPE: Semiconductor Production Equipment



^{2.} Percentages on the graph show the composition ratio of new equipment sales. Field Solutions sales are not included.

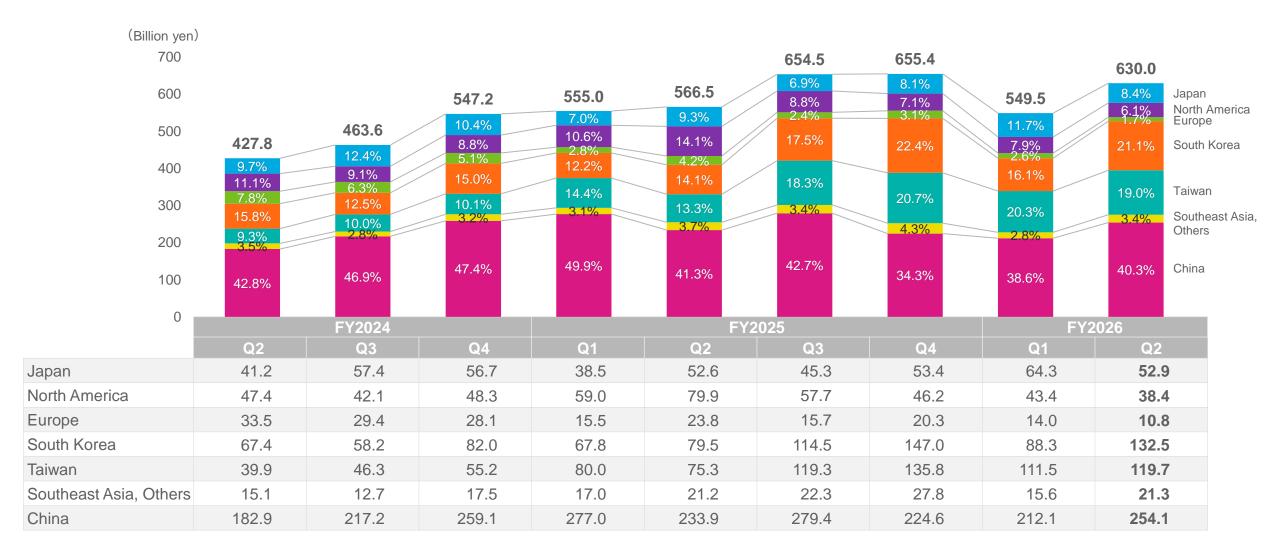
Field Solutions Sales (Quarterly)

(Billion yen) 200





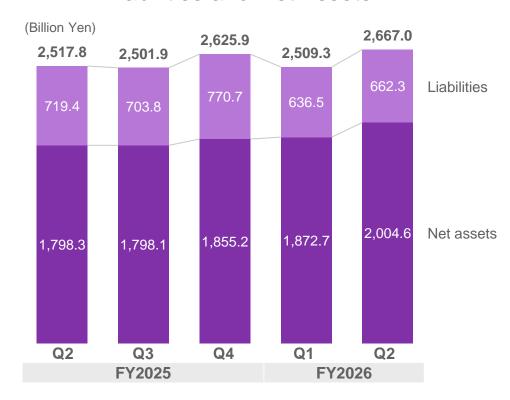
Composition of Net Sales by Region (Quarterly)



Balance Sheet (Quarterly)

Assets (Billion Yen) 2,667.0 2,625.9 2,517.8 2,501.9 2,509.3 455.2 Cash and cash equivalents* 496.2 295.5 367.5 525.5 Notes and accounts receivable (trade, and 393.2 contract assets) 720.4 Inventories 757.1 765.0 749.1 742.2 85.4 Other current assets 75.3 75.0 69.7 70.6 561.2 Tangible assets 480.3 431.4 389.2 441.7 31.8 34.2 35.5 35.7 Intangible assets 35.8 400.2 386.5 389.6 397.4 Investment and other assets 347.6 Q2 Q3 **Q4** Q1 Q2 FY2025 FY2026

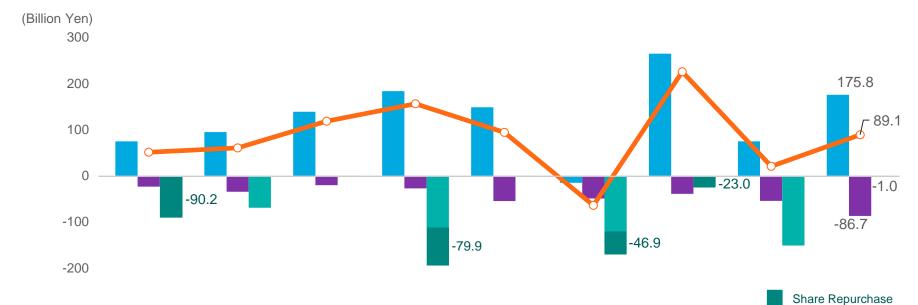
Liabilities and Net Assets



^{*}Cash and cash equivalents: "Cash and deposits" + "Short-term investments", etc. ("Securities" in Balance Sheet).



Cash Flow (Quarterly)



| -300 | | | | | | | | | <u>'</u> |
|---------------------------------------|--------|-------|-------|--------|-------|--------|-------|--------|----------|
| | FY2024 | | | FY2025 | | | | FY2026 | |
| | Q2 | Q3 | Q4 | Q1 | Q2 | Q3 | Q4 | Q1 | Q2 |
| Cash flow from operating activities | 74.8 | 95.0 | 139.0 | 183.7 | 148.6 | -15.0 | 264.8 | 74.9 | 175.8 |
| Cash flow from investing activities*1 | -23.4 | -34.4 | -20.3 | -27.3 | -54.4 | -49.0 | -38.9 | -54.1 | -86.7 |
| Cash flow from financing activities | -90.8 | -69.3 | -0.6 | -194.4 | -0.6 | -170.1 | -23.5 | -151.1 | -1.0 |
| ◆ Free cash flow*2 | 51.4 | 60.6 | 118.7 | 156.4 | 94.1 | -64.1 | 225.8 | 20.7 | 89.1 |
| Cash on hand*3 | 362.6 | 352.4 | 472.5 | 438.5 | 525.5 | 295.5 | 496.2 | 367.5 | 455.2 |

^{*1} Cash flow from investing activities excludes changes in time deposits and short-term investments.

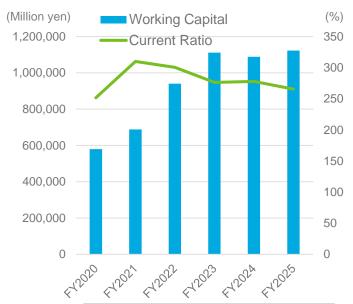


^{*2} Free cash flow = "Cash flow from operating activities" + "Cash flow from investing activities" (excluding changes in "Time deposits" and "Short-term investments").

^{*3} Cash on hand includes "Cash and cash equivalents" + "Time deposits and short-term investments" with original maturities of more than three months.

Asset Related Indices

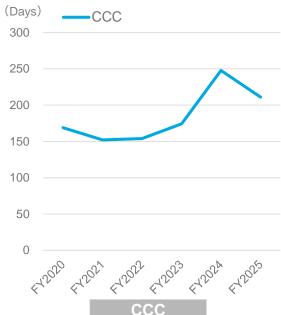
Working Capital and **Current Ratio**



| | Working Capital | Current Ratio |
|--------|-----------------|---------------|
| | (Million yen) | (%) |
| FY2020 | 579,905 | 251.6 |
| FY2021 | 688,035 | 310.0 |
| FY2022 | 940,124 | 300.6 |
| FY2023 | 1,111,065 | 276.4 |
| FY2024 | 1,088,552 | 277.9 |
| FY2025 | 1,122,830 | 265.6 |

Working capital = Current assets - Current liabilities Current ratio = Current assets / Current liabilities × 100

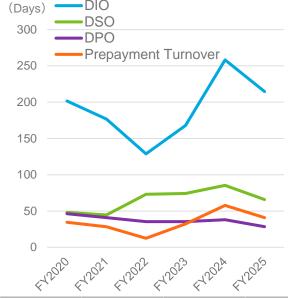
Cash Conversion Cycle (CCC)



| | CCC |
|--------|--------|
| | (Days) |
| FY2020 | 169 |
| FY2021 | 152 |
| FY2022 | 154 |
| FY2023 | 174 |
| FY2024 | 248 |
| FY2025 | 211 |

Cash conversion cycle = DIO + DSO - Advances turnover - DPO

Inventory (DIO) / Receivable (DSO) / Payable (DPO) / Advances Turnover



| | DIO (Days) | DSO (Days) | DPO (Days) | Advances (Days) |
|--------|---------------|---------------|---------------|--------------------|
| FY2020 | 202 | 48 | 46 | 34 |
| FY2021 | 177 | 45 | 41 | 28 |
| FY2022 | 129 | 73 | 35 | 12 |
| FY2023 | 168 | 74 | 35 | 32 |
| FY2024 | 258 | 85 | 38 | 58 |
| FY2025 | 215 | 66 | 28 | 41 |

DIO = Average inventories / Cost of goods sold *365



DSO = Average accounts receivable* / Revenue *365

^{*}Accounts receivable includes contract assets

DPO = Accounts payable / Cost of goods sold *365

Consolidated 10-year Financial Summary

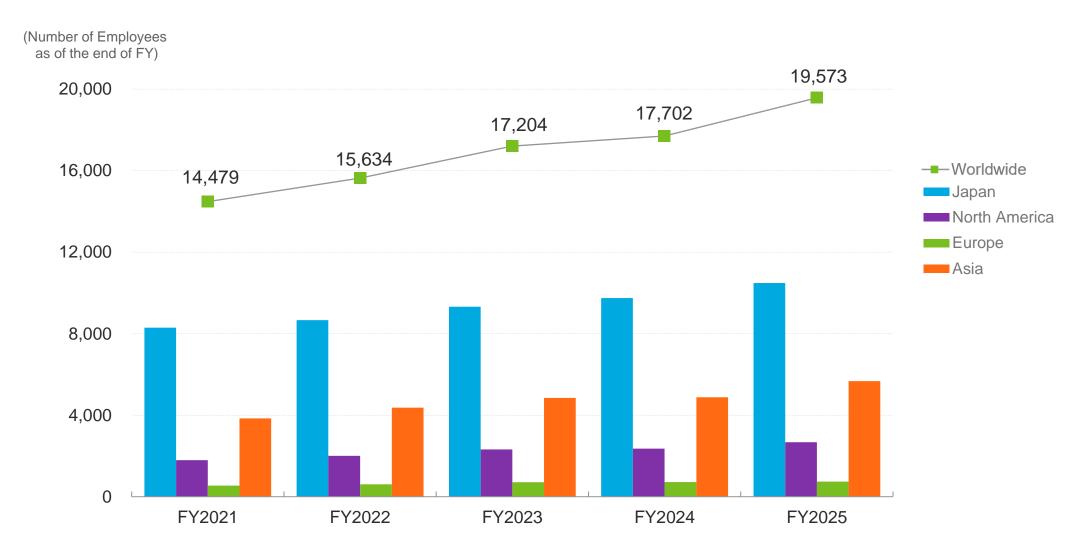
(Millions of yen)

| FY2016 663,949 267,209 40.2% 150,420 116,789 | FY2017 799,719 322,291 40.3% | FY2018 1,130,728 475,032 | FY2019 1,278,240 | FY2020 1,127,286 | FY2021 1,399,102 | FY2022 | FY2023 | FY2024 | FY2025 |
|---|---|--|---|---|---|--|---|---|--|
| 267,209 40.2% 150,420 | 322,291 | | 1,278,240 | 1.127.286 | 1 200 102 | 0.000.005 | | | |
| 40.2% 150,420 | | 475.032 | | .,, | 1,399,102 | 2,003,805 | 2,209,025 | 1,830,527 | 2,431,568 |
| 150,420 | 40.3% | -, - | 526,183 | 451,941 | 564,945 | 911,822 | 984,408 | 830,269 | 1,146,287 |
| | | 42.0% | 41.2% | 40.1% | 40.4% | 45.5% | 44.6% | 45.4% | 47.1% |
| 116.789 | 166,594 | 193,860 | 215,612 | 214,649 | 244,259 | 312,551 | 366,684 | 374,006 | 448,967 |
| , | 155,697 | 281,172 | 310,571 | 237,292 | 320,685 | 599,271 | 617,723 | 456,263 | 697,319 |
| 17.6% | 19.5% | 24.9% | 24.3% | 21.0% | 22.9% | 29.9% | 28.0% | 24.9% | 28.7% |
| 119,399 | 157,549 | 280,737 | 321,662 | 244,979 | 322,103 | 601,724 | 625,185 | 463,185 | 707,727 |
| 106,467 | 149,116 | 275,242 | 321,508 | 244,626 | 317,038 | 596,698 | 624,856 | 473,439 | 706,114 |
| 77,892 | 115,208 | 204,371 | 248,228 | 185,206 | 242,941 | 437,076 | 471,584 | 363,963 | 544,133 |
| 76 287 | 83 800 | 97 103 | 113 080 | 120 268 | 136 648 | 158 256 | 101 106 | 202 873 | 250,017 |
| | - | | | _ | | | | | 162,171 |
| 19,257 | 17,872 | 20,619 | 24,323 | 29,107 | 33,843 | 36,727 | 42,927 | 52,339 | 62,148 |
| | | | | | | | | | |
| - | - | - | - | - | - | - | - | - | - |
| 562,369 | 643,094 | 767,146 | 880,748 | 819,301 | 1,012,977 | 1,335,152 | 1,587,595 | 1,746,835 | 1,839,929 |
| 793,367 | 957,447 | 1,202,796 | 1,257,627 | 1,278,495 | 1,425,364 | 1,894,457 | 2,311,594 | 2,456,462 | 2,625,981 |
| _ | - | - | - | - | _ | _ | | | _ |
| 70.9% | 67.2% | 63.8% | 70.0% | 64.1% | 71.1% | 70.5% | 68.7% | 71.1% | 70.1% |
| 13.0% | 19.1% | 29.0% | 30.1% | 21.8% | 26.5% | 37.2% | 32.3% | 21.8% | 30.3% |
| | | | | | | | | | |
| | | | _ | 253,117 | | | | | 582,174 |
| | | | | 15,951 | | | | | -169,609 |
| -138,600 | -39,380 | -82,549 | -129,761 | -250,374 | -114,525 | -167,256 | -256,534 | -325,012 | -388,836 |
| 153.70 | 234.09 | 415.16 | 504.53 | 390.19 | 520.73 | 935.95 | 1,007.82 | 783.75 | 1,182.40 |
| 79.00 | 117.00 | 208.00 | 253.00 | 196.00 | 260.00 | 468.00 | 570.00 | 393.00 | 592.00 |
| | 11,241 | | | | | | | | |
| | - 562,369 793,367 - 70.9% 13.0% - 69,398 -150,013 -138,600 | 13,341 20,697 19,257 17,872 562,369 643,094 793,367 957,447 70.9% 67.2% 13.0% 19.1% 69,398 136,948 -150,013 -28,893 -138,600 -39,380 | 13,341 20,697 45,603 19,257 17,872 20,619 - - - 562,369 643,094 767,146 793,367 957,447 1,202,796 - - - 70.9% 67.2% 63.8% 13.0% 19.1% 29.0% 69,398 136,948 186,582 -150,013 -28,893 -11,833 -138,600 -39,380 -82,549 153.70 234.09 415.16 | 13,341 20,697 45,603 49,754 19,257 17,872 20,619 24,323 - - - - 562,369 643,094 767,146 880,748 793,367 957,447 1,202,796 1,257,627 - - - - 70.9% 67.2% 63.8% 70.0% 13.0% 19.1% 29.0% 30.1% 69,398 136,948 186,582 189,572 -150,013 -28,893 -11,833 -84,033 -138,600 -39,380 -82,549 -129,761 153.70 234.09 415.16 504.53 | 13,341 20,697 45,603 49,754 54,666 19,257 17,872 20,619 24,323 29,107 - - - - - - 562,369 643,094 767,146 880,748 819,301 793,367 957,447 1,202,796 1,257,627 1,278,495 - | 13,341 20,697 45,603 49,754 54,666 53,868 19,257 17,872 20,619 24,323 29,107 33,843 - - - - - 562,369 643,094 767,146 880,748 819,301 1,012,977 793,367 957,447 1,202,796 1,257,627 1,278,495 1,425,364 - - - - - 70.9% 67.2% 63.8% 70.0% 64.1% 71.1% 13.0% 19.1% 29.0% 30.1% 21.8% 26.5% 69,398 136,948 186,582 189,572 253,117 145,888 -150,013 -28,893 -11,833 -84,033 15,951 -18,274 -138,600 -39,380 -82,549 -129,761 -250,374 -114,525 153.70 234.09 415.16 504.53 390.19 520.73 | 13,341 20,697 45,603 49,754 54,666 53,868 57,288 19,257 17,872 20,619 24,323 29,107 33,843 36,727 - - - - - - - - 562,369 643,094 767,146 880,748 819,301 1,012,977 1,335,152 793,367 957,447 1,202,796 1,257,627 1,278,495 1,425,364 1,894,457 - - - - - - - - 70.9% 67.2% 63.8% 70.0% 64.1% 71.1% 70.5% 13.0% 19.1% 29.0% 30.1% 21.8% 26.5% 37.2% 69,398 136,948 186,582 189,572 253,117 145,888 283,387 -150,013 -28,893 -11,833 -84,033 15,951 -18,274 -55,632 -138,600 -39,380 -82,549 -129,761 -250,374 -114,525 -167 | 13,341 20,697 45,603 49,754 54,666 53,868 57,288 74,432 19,257 17,872 20,619 24,323 29,107 33,843 36,727 42,927 - - - - - - - - - 562,369 643,094 767,146 880,748 819,301 1,012,977 1,335,152 1,587,595 793,367 957,447 1,202,796 1,257,627 1,278,495 1,425,364 1,894,457 2,311,594 - <td>13,341 20,697 45,603 49,754 54,666 53,868 57,288 74,432 121,841 19,257 17,872 20,619 24,323 29,107 33,843 36,727 42,927 52,339 -</td> | 13,341 20,697 45,603 49,754 54,666 53,868 57,288 74,432 121,841 19,257 17,872 20,619 24,323 29,107 33,843 36,727 42,927 52,339 - |

- 1. From FY2019, the Company adopts "Partial Amendments to Accounting Standard for Tax Effect Accounting" (ASBJ Statement No. 28, revision on February 16, 2018). "Total assets" and "equity ratio" for FY2018 have been restated in the table in accordance with the revised accounting standard.
- 2. From the beginning of FY2022, the Company applies "Accounting Standard for Revenue Recognition" (ASBJ Statement No. 29).
- 3. The Company implemented a 3-for-1 common stock split on April 1, 2023. Net income per share and dividend per share (yen) are the figures after the stock split.
- 4. Some of the data featured in this Investors' Guide is available for download in Excel format from the "Data Book" section on our website.

https://www.tel.com/ir/library/fb/

Worldwide Employees





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- Processing of numbers
 For the amount listed, because fractions are rounded down, there may be the cases where the total for certain account titles does not correspond to the sum of the respective figures for account titles. Percentages are calculated using full amounts, before rounding.
- Foreign exchange risk
 In principle, export sales of Tokyo Electron's products is denominated in yen. Although some sales and expenses are denominated in foreign currencies, the impact of foreign exchange rate fluctuations on profits is negligible, unless extreme fluctuations occur.
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